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# Metal-organic framework thin films as versatile chemical sensing materials

James E. Ellis,†a Scott E. Crawford to †a and Ki-Joong Kim \*b \*ab

Metal-organic frameworks (MOFs) have been widely investigated as chemical sensing materials due to their periodic porosity, tunable chemical functionalities such as Lewis acid/base sites, potential conductivity and/or sensitive optical properties. However, most sensor devices require the integration of the sensing material as a thin film, which presents significant synthetic and stability challenges for MOF materials. In this review, we provide a background on why MOFs are excellent candidates for the chemical sensing of various analytes (i.e. gases, ions, pH), as well as different techniques for MOF thin film growth and the challenges associated with each method. Examples of different MOF thin film chemical sensor devices will be discussed, as well as their various transduction mechanisms: electrical, optical, and acoustic. The review concludes with an outlook on potential future innovations for MOF thin film chemical sensors, and the remaining challenges associated with real-world implementation.

## 1. Introduction

## 1.1 MOF thin films as sensing materials

Metal-organic frameworks (MOFs), also known as porous coordination polymers, are crystalline nanoporous materials that

- <sup>a</sup> National Energy Technology Laboratory, 626 Cochrans Mill Road, Pittsburgh, Pennsylvania, 15236, USA. E-mail: ki-joong.kim@netl.doe.gov; Tel: +1-412-386-4526
- <sup>b</sup> NETL Support Contractor, 626 Cochrans Mill Road, Pittsburgh, Pennsylvania 15236, USA
- † These authors contributed equally.

are built from metal ions or metal-containing clusters (i.e. secondary building units) connected by organic linkers to form a two-dimensional (2D) or three-dimensional (3D) extended network. Due to the diversity of available metal ions and organic linkers, and the variety of possible coordination linkages, there are theoretically unlimited types of potential MOF structures, and more than 70000 MOF species have been reported so far, according to Cambridge Structural Database (CSD) subset.1

In the early stages of MOF research, the synthesis of MOFs mainly focused on a systematic design and construction



Iames E. Ellis

James E. Ellis is a research scientist for Leidos Inc. at National Energy Technology Laboratory, where he investigates electrochemical CO2 reduction catalysis. He obtained his PhD in Inorganic Chemistry from the University of Pittsburgh in 2018 under the supervision of Prof. Alexander Star, where he studied inorganic/ carbon nanomaterial composites and their application as chemical sensing materials. He was an Oak Ridge Institute for Science and

Education (ORISE) postdoctoral researcher at NETL from 2019-2021 where he investigated porous nanomaterial, primarily metalorganic frameworks, thin films as sensing elements in optical fiberbased sensors.



Scott E. Crawford

Scott E. Crawford is currently an Analytical Chemist at Leidos Inc.-National Energy Technology Laboratory, where he develops optical sensors for high value metals. He obtained his PhD in Analytical Chemistry from the University of Pittsburgh in 2019 under the supervision of Prof. Jill Millstone, where he studied the impact of surface chemistry on the optical and charge transfer properties of luminescent coinage metal nanoparticles. Notable recogni-

tions include the Mickey Leland Energy Fellowship, the Eastern Analytical Symposium Graduate Student Award, the University of Pittsburgh Andrew Mellon Predoctoral Fellowship, and the Society for Chemical Industry Scholar Award.

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through coordination chemistry.<sup>2-4</sup> Later, research was dedicated to developing highly porous MOF materials with the ability for low temperature and pressure gas adsorption of energy-relevant gases such as CO<sub>2</sub>, CH<sub>4</sub>, H<sub>2</sub>, etc. At present, MOFs have exhibited potential for practical applications in many fields, such as catalysis,5 micro-electronic devices6,7 and sensors.<sup>8,9</sup> Certainly, the most impressive traits of MOFs are their extremely high surface areas and tunable pore sizes. which present remarkable advantages over other porous materials (e.g. zeolites and activated carbons). Moreover, MOFs may have luminescent, magnetic, electrical conductivity, and catalytic properties, which make them of particular interest in various fields including chemical sensing. For sensor applications, the MOF should be able to be integrated on devices as a thin film, which is a prerequisite for their deployment in the field<sup>10</sup> However, for initial MOF-based sensing studies, MOF films were usually prepared as pre-synthesized bulk powders, <sup>11</sup> which made device processing with these insoluble materials difficult. As a result, integration of MOF materials was typically performed from suspensions of particles which may lead to brittleness, difficulty in spatial control, and overall poor processability.11 To address these challenges, there have been an increasing number of studies devoted to developing effective fabrication methods for high-quality MOF films targeted towards practical applications.8,9

In recent years, well-defined MOF thin films on various sensor platforms have been reported. 12,13 While diverse MOF films and their applications have been demonstrated, this field is still at an emerging stage with several remaining issues. Indeed, the development of MOF-based sensing technologies



**Ki-Joong Kim** 

Ki-Joong Kim is a research scientist with LRST working as an research support contractor at National Energy Technology Laboratory, US Department of Energy, where he focus on the nano-composite thin film synthesis for chemical sensor applications. He obtained his PhD degree chemical engineering from Sunchon National University, South Korea, in 2009 under the supervision of Prof. Ho-Geun Ahn, where he studied catalytic reaction

engineering on supported nanomaterials. He was a Postdoctoral scholar at Oregon State University, where he focused on solutionbased nanomaterials synthesis and use them for energy and environmental applications such as photocatalysts and photovoltaic cells. At NETL, he is involving in developing the sensing materials for carbon dioxide monitoring (including pH monitoring) in carbon storage applications and for methane leak detection in natural gas infrastructure, and detection of such species in wellbore integrity monitoring and drilling applications amongst others.

necessitates further innovation in fabrication techniques to produce high-quality thin films. In this review, we focus on the recent progress in the development of MOF thin films and their application in various chemical sensor devices, including electrical, optical, and acoustic-based sensors.

#### 1.2 Fabrication of MOF thin films

There has been significant research in the area of MOF thin film syntheses, and the multitude of techniques that have been developed has been the subject of several comprehensive reviews. 9,14-16 A number of factors must be considered when selecting a fabrication technique: reaction time/temperature, the use of specialized equipment, scalability, film quality, and the sensing technique being used will all guide the choice of synthetic method.

Common synthetic methods used to prepare MOF thin films can be divided into four broad categories: (1) ex situ, (2) in situ, (3) templated in situ, and (4) seeding or secondary growth.

**1.2.1** Ex situ. Ex situ methods include drop-casting (also known as solvent casting),17 dip-coating,18 spin-coating,19 Langmuir–Blodgett, 20 and various printing techniques. 21 In these methods MOF (nano)crystals are first synthesized and dispersed into a solution, ideally as a colloid, and then coated onto the substrate through some mechanical means. Evaporation of the solvent creates a film of the remaining MOF crystals on the surface of the substrate. Ex situ methods are commonly used to create thin films of a variety of materials including metal nanoparticles, 22 polymers, 23 or supramolecular complexes. 24 Besides the versatility of ex situ methods, they also allow the size of the particles to be controlled since the particle synthesis step is decoupled from the film deposition step. The simplest of these methods, drop-casting, is simply the evaporation of a droplet of the MOF solution on the surface of the substrate. Simplicity is the greatest advantage of this method; however, its disadvantages include high variability in surface coverage on the substrate (e.g. the coffee ring effect), high variability between substrates, and surface defects such as cracks and holes within the thin film.<sup>25</sup> Certain parameters can be controlled to minimize these disadvantages, such as the choice of solvent, temperature, surface functionalization, and even the angle of the substrate. 26-29 Dip-coating and spin-coating share the same disadvantages of drop-casting; however, they include more parameters that can be optimized to reduce these faults. For dip-coating, the speed of the substrate moving across the liquid-air interface can affect the film quality.30 Though dipcoating can be done manually, automated dip-coated machines reduce variability between substrates.18 For spin-coating, the spin speed and ramp rate highly affect the film thickness and quality.

1.2.2 In situ. Unlike ex situ methods, in situ methods couple the synthesis of MOF nanocrystals to the formation of the thin film to the substrate surface. Solvothermal MOF syntheses with the substrate present in the reaction solution will typically result in a weak and scattered association of MOF nanocrystals with the substrate surface, but the vast majority of MOF nucleation will occur in solution. 10 In order to increase

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the coverage and attachment strength of the MOF thin film to the substrate surface, the substrate will often require a surface functionalization process prior to the solvothermal reaction.9 Functionalization of the substrate surface with molecules that increase the local concentration of reactants and intermediates close to the substrate surface via intermolecular interactions will promote MOF nucleation and subsequent film growth on the substrate surface. 31 The main advantage of this method over ex situ methods is the adhesion strength of the MOF film to the substrate. Another in situ MOF thin film method is layerby-layer growth. This method alternately exposes the substrate surface area between the metal precursor solution and organic precursor solution with wash steps in between.<sup>32</sup> Layer-by-layer (LbL) is usually used in conjunction with surface functionalization of the substrate. This method allows fine control over the thickness of the resulting MOF film since each iteration of the method will typically grow <1 nm of MOF film.<sup>33</sup> While fine thickness control may be an advantage, it can also be a disadvantage since the achievement of thick films may become time- and/or labor-intensive. However, innovations in layer-bylayer growth methods, such as automated spin-coating systems, dramatically reduce the time and labor previously required. 34,35

1.2.3 In situ (template-assisted). Template-assisted in situ methods use the metal atoms incorporated within the substrate (metal or metal oxide) as a precursor for MOF thin film growth. These methods include electrochemical, <sup>36</sup> microwave-assisted, <sup>37</sup> and ceramic templating.38 Electrochemical MOF film growth is performed by placing a metal substrate in the organic ligand precursor solution and applying sufficient electrical potential to the substrate to coordinate organic ligands in solution to metal

atoms on the substrate.14 Instead of electrical energy, microwaveassisted growth method utilizes high thermal energy on the metallic substrate formed via microwave radiation to drive coordination between organic ligands in solution and metal atoms on the substrate.<sup>39</sup> In short, electrochemical and microwave-assisted growth methods produce high electrical or thermal energies, respectively, at the surface of the metallic substrate to initiate coordination and subsequent film growth. Ceramic template growth methods typically involve the solvothermal treatment of a metal oxide substrate in organic ligand precursor solution.<sup>40</sup> At sufficiently high temperatures and pressures, the metal atoms in the metal oxide substrate will coordinate with organic ligands in solution and lead to MOF thin film formation on the substrate. The primary advantages of these template-assisted growth methods is the high adhesions strength of the resulting MOF thin films to the substrate, as well as the potential for patterning since MOF film will only grow where metal atoms are present. The main disadvantage of these methods is that they are energyintensive and require expensive equipment (e.g. potentiostat). However, it has been recently demonstrated that certain metal oxides can be converted to more reactive intermediates, namely hydroxy double salts (HDS), which can react with organic ligands to form MOF thin films even at ambient conditions.41

1.2.4 Seeding (secondary growth). Seeding or secondary growth methods involve a two-step process wherein MOF "seeds" are first synthesized and decorated onto the substrate surface. The seed-decorated substrate is then submerged in MOF growth solution to form a MOF film on the substrate surface. 42 The primary advantage of this technique is the possibility of using physical features on the substrate's micro-surface, such as holes

Table 1 Summary of common MOF thin film fabrication techniques

Technique	Advantages	Disadvantages
Ex situ	Control of nanoparticle size, rapid (<1 min)	Poor adhesion
Drop-cast	Simple method	Heterogeneity in film thickness, film defects ( <i>e.g.</i> cracks and pinholes), not appropriate for large substrates (>25 mm <sup>2</sup> ), limited to planar substrates
Spin-coat	Good control over film thickness	Requires expensive equipment, limited to planar substrates smaller than spin-coater
Dip-coat	Simple method, can be applied on range of substrate sizes, can be combined with surface functionalization	Heterogeneity in film thickness, film defects (e.g. cracks and pinholes)
Contact printing	Patternable method	Low patterning resolution
Ink-jet printing and spray coating	Patternable method, can be applied on large size range	Requires expensive equipment, low patterning resolution
Surface-assisted (e.g. Langmuir– Blodgett)	Very fine control over film thickness, can be combined with surface functionalization	May require expensive equipment, limited to planar substrates
In situ	Better substrate adhesion than <i>ex situ</i> , can be combined with surface functionalization ( <i>e.g.</i> SAM)	Poor control over nanoparticle size, growth not limited to substrate
Solvothermal	Simple method	Film defects (e.g. cracks, pinholes, corrugation), requires high temperature, time intensive
LbL	Fine control over film thickness, good control over crystal orientation, compatible with automation	Potentially time intensive
In situ (template-assisted)	Strong adhesion, patternable	Requires expensive equipment, poor control over nanoparticle size
Electrochemical	_	Limited to metallic substrates
Ceramic template	Can be combined with CVD	_
Microwave-assisted	Rapid growth	_
Seeding (secondary growth)	Patternable	Growth not limited to substrate, poor adhesion

B. In-situ (Direct growth) Bare Drop-coat Spin-coat A. Ex-situ Spray-coat Langmuir-Blodgett Hent MOF NP Bare MOF NE Metal MOF thin film substrate dispersion thin film Organic Surface precursors functionalized C. In-situ (Layer-by-layer) Bare D. In-situ (Template-assisted) Dip-coat Spin-coat Templated Spray-coat Metal Organic MOF thin film Templated Organic MOF thin film precursors precursors metal source precursor Surface functionalized Seeding (Secondary growth

MOF

seed layer

ig. 1 Schematic depictions of the most common MOF thin film synthesis (or deposition) methods

Seed

solution

Physical

/chemical

template

and troughs, to pattern seed decoration and subsequent film growth. The disadvantages of seeding methods are potential detachment of seeds in the growth solution and poor adhesion of the film to the substrate surface.

Table 1 summarizes the general advantages and disadvantages of each technique, while Fig. 1 provides a schematic of the fabrication method. These techniques may be applied to deposit MOF films on a range of substrates depending upon the sensing technique. For example, optical fibers and/or quartz substrates are often employed for optical sensing techniques. Acoustic-based methods, on the other hand, require the MOFs to be deposited on planar substrates such as quartz crystal microbalances (QCM) and surface acoustic wave (SAW) devices. The film quality required is also somewhat dependent upon the sensing technique being deployed. As discussed in subsequent sections, high quality MOF films (e.g. uniformity, crystallinity, smooth surfaces, no bare patches, etc.) are required for absorbance-based and acoustic-based sensing techniques, whereas film quality is less important for luminescence-based sensors. Many of the fabrication techniques are desirable due to their inherent simplicity. For example, dip-coating, 43 dropcasting, and the use of sacrificial templates typically do not require any specialized equipment and produce films relatively quickly. Yet there are drawbacks for each technique; dipcoating and drop-casting techniques, much like the layer-bylayer (LbL) method, often require multiple cycles to produce films of sufficient thickness in sensing applications. The use of a sacrificial template can be used to rapidly produce a MOF film in one step;41 however, only a select few MOF structures have been prepared using this synthetic method. Strategies requiring relatively expensive equipment include spin coating, electrochemical synthesis, microwave heating, and, when using a commercial apparatus, dip-coating, which can all be employed to produce films of relatively high quality and various thickness. Emerging fabrication methods (see Section 5.2) include solvent-free chemical vapor deposition (CVD) and other gas phase processes, 44-46 which offer advantages in terms of scalability and morphological control, but require expensive and sophisticated equipment.

Templated

MOF thin film

Growth

solution

## 2. Electrical MOF thin film sensors

Electrical transduction of chemical interactions is a popular sensing approach because of (1) the extensive and well-known

capabilities for electrical sensor fabrication and (2) the various electrical-based sensing mechanisms that provide theoretical pathways for enhanced sensitivity and selectivity. The working principle behind electrical chemical sensors is that chemical interactions between the target analyte and sensing material can cause changes in the electronic properties of the sensing material. Mechanisms for this working principle include intramolecular mechanisms (e.g. charge transfer, trap state formation), intermolecular mechanisms (e.g. swelling), or a combination that effects a change in the sensing material's charge concentration, charge mobility, or charge distribution. On the macroscale, these electronic events are reflected as changes in the material's resistance, permittivity (and consequently capacitance), and/or work function. Besides being a selective and sensitive sensing approach, electrical sensors have the additional benefit of potential miniaturization and integration with other electronic devices such as smartphones.

MOF thin films have been used as the sensing layer in various types of electrical sensors including chemiresistors, chemicapacitors, and field-effect transistors (FETs). 12,47-49 MOF thin film electrical-based sensors are summarized in Table 2. The attraction of using MOFs as the sensing material for electrical sensors lies in their high porosity, chemical tailorability, and potential functionalization. While the majority of MOFs are nonconductive, the advent of conductive MOFs has paved the way for their integration into chemiresistors.<sup>50</sup> The dual nature of MOFs creates a variety of potential active sites a target analyte may interact with. For example, reducing gases such as NH3 have strong interactions with open metal sites (OMS),<sup>51</sup> while electrophilic analytes like CO<sub>2</sub> are more likely to adsorb to a Lewis basic organic ligand.<sup>52</sup>

#### 2.1 Chemiresistive sensors

In its simplest form, a chemiresistor sensing device is composed of two electrodes deposited on an insulating substrate with a conductive sensing material bridging the electrodes. The conductive sensing material serves as a variable resistor in the circuit whereby changes in the chemical environment modulate the resistance of the material. This modulation of resistance can be caused by charge transfer, introduction of electronic trap states or scattering sites that affect charge mobility or shifting of the Schottky barrier between the sensing material and electrode. Due to mismatched energy levels and poor orbital overlap between the metal centers and organic ligands, most 3D MOFs do not display conductivity under ambient conditions. However, the recent advent of conductive 2D MOFs that have in-plane charge delocalization and extended  $\pi$ -d conjugation has led to numerous examples of MOF-based chemiresistors.<sup>50</sup> A mechanistic study of these conductive 2D MOFs found that their chemiresistive response towards a target analyte is related to its binding on the OMS of the MOF.<sup>51</sup>

The first example of a MOF-based chemiresistor was prepared from drop-cast films of Cu<sub>3</sub>(HITP)<sub>2</sub> (HITP = 2,3,6,7,10,11hexaiminotriphenylene), a conductive 2D MOF. 70 The electrical conductivity of this MOF can be attributed to the large aromatic

core of HITP and favorable orbital overlap between the Cu2+ metal center and the imine base, which results in an extended  $\pi$ -d conjugation network along the *ab* plane. This 2D MOF displayed a bulk conductivity of 0.2 S cm<sup>-1</sup>, which is more than enough conductivity to be applied in a chemiresistor device. In this work, bulk Cu<sub>3</sub>(HITP)<sub>2</sub> was synthesized, dispersed in solution, and drop-cast onto interdigitated electrodes (IDEs) to create a chemiresistor device that was sensitive to NH<sub>2</sub> vapor. As a continuation of this work, three different conductive 2D MOFs were prepared to construct a cross-reactive sensor array that allowed for clear discrimination of volatile organic compounds (VOCs).69 The three conductive 2D MOFs prepared in this work were  $Cu_3(HITP)_2$ ,  $Ni_3(HITP)_2$ , and  $Cu_3(HHTP)_2$  (HHTP = 2,3,5,6,10,11-hexahydroxytriphenylene). This approach of using chemiresistor arrays in conjunction with principle component analysis (PCA) can provide discrimination between different target analytes and concentration ranges. A recent example of this approach utilized a series of isoreticular nickel metallophthalocyanine (NiPc) and metallonaphthalocyanine (NiNPc) frameworks. 63 Frameworks were synthesized by "welding" NiPcs and NiNPcs together with Cu2+ and Ni2+ cations, producing a total of four unique frameworks: NiPc-Ni, Ni-NPc-Ni, NiPc-Cu, and NiNPc-Cu. Compared to single molecule NiPc or NiNPc, welding these subunits into frameworks improved conductivity by 5-7 orders of magnitude. The excellent intrinsic conductivity (up to 10<sup>-2</sup> S cm<sup>-1</sup>) of the frameworks allowed the sensor to be operated at low driving voltages (0.01-1.0 V). PCA applied toward the chemiresistor responses of these conductive MOFs provided discrimination of ppm levels of NO, NH<sub>3</sub>, and H<sub>2</sub>S, even in the presence of 18% relative humidity. These NiPc and NiNPc framework chemiresistor sensors displayed excellent sensitivity toward NH<sub>3</sub> (limits of detection (LOD): 0.31-0.33 ppm), H<sub>2</sub>S (LOD: 19-32 ppb), and NO (LOD: 1.0-1.1 ppb).

There have been several examples of in situ growth of conductive 2D MOFs on chemiresistive devices. Mirica and co-workers developed an in situ synthetic method to grow two different conductive 2D MOFs, Cu<sub>3</sub>(HHTP)<sub>2</sub> and Ni<sub>3</sub>(HHTP)<sub>2</sub>, on a shrinkable polymer substrate with graphite electrodes. 68 Thick films (5-10 µm) of these 2D MOF were grown on a polymer substrate by submerging the substrate in the MOF growth solution for a set time period (Fig. 2A-D). An array of these chemiresistors were able to distinguish between NH<sub>3</sub>, H<sub>2</sub>S, and NO (Fig. 2E and F) as well as different concentration ranges (Fig. 2G and H). An advantage of this synthetic method is its adaptability to different substrates. This in situ synthetic method was utilized to grow conductive 2D MOFs on textile fibers, allowing chemiresistor devices to be prepared on fabric.<sup>67</sup> The combination of the textile's mesoporosity with the MOF's microporosity makes a device of enhanced porosity that translates into excellent gas sensing ability. At the time of publication, this work showed the best performance of any smart fabric sensor or MOF-based chemiresistor toward NO and H<sub>2</sub>S detection, displaying LODs for NO and H<sub>2</sub>S of 0.16 ppm and 0.23 ppm, respectively. Unlike H<sub>2</sub>S, NO, or NH<sub>3</sub>, CO2 is not a strong electron donating or accepting molecule,

MOF thin film electrical-based sensors

Material	Film growth method	Device type	Target analyte	Sensing range (ppm)	Film thickness (µm)	LOD (ppb)	Ref.
Mg-MOF-74	Solvothermal	Chemicapacitor	Benzene, CO <sub>2</sub>	5-100, 200-5000	7.00	_	53
Ni-MOF-74	Metal oxide template	Chemicapacitor	Benzene	25-100	0.09	_	54
MFM-300	Solvothermal	Chemicapacitor	$SO_2$	0.075 - 1	_	5	55
fum-fcu-MOF	Solvothermal	Chemicapacitor	$H_2S$	0.1 - 100	_	5	56
NbOFFIVE-1-Ni/AlFFIVE-1-Ni	Spin-coat	Chemicapacitor	$CO_2$	400-5000	2.00	_	57
CuBTC	Drop-cast	Chemicapacitor	Methanol, ethanol, isopropanol, acetone	250-1500	8.00	61 990, 71 050, 77 800, 100 180	58
Cu(bdc)·xH <sub>2</sub> O	LbL	Chemicapacitor	Humidity, VOCs	_	1.50	_	59
CuBTC	Electrochemical	Chemicapacitor	Methanol, ethanol	200-2000	5.00	39 100, 130 000	29
NDC-Y-fcu-MOF	Solvothermal	Chemicapacitor	$NH_3$	1-100	_	92	60
$Cu_3(HITP)_{2-x}(HHTP)_x$	Spray LbL	Chemiresistor	Benzene	1-100	0.02 - 0.07	24-96	61
Cu <sub>3</sub> (HHTP)(THQ)	Drop-cast	Chemiresistor	$NH_3$	1-100	_	20-350	62
M(Cu, Ni) phthalocyanines, M(Cu, Ni) naphthalocyanines	Drop-cast	Chemiresistor array	NO, H <sub>2</sub> S, NH <sub>3</sub>	0.02-1, 0.2-80, 2- 80	1-6	1, 19–32, 310– 330	63
Cu <sub>3</sub> (HHTP) <sub>2</sub> /M(Pt, Pd) NPs	Drop-cast	Chemiresistor	$NO_2$	1-5	_	_	64
Cu <sub>3</sub> (HHTP) <sub>2</sub> /Cu <sub>3</sub> (TCPP) <sub>2</sub>	Spray LbL and interface-assisted dip-cast	Chemiresistor	NH <sub>3</sub> , benzene	1-100	0.075	120 (benzene)	65
$Cu_3(HIB)_2$	Drop-cast	Chemiresistor	$CO_2$	400-2500	_	_	52
Cu <sub>3</sub> (HHTP) <sub>2</sub>	Spray LbL	Chemiresistor	$NH_3$	1-100	0.02	600	66
Ni <sub>3</sub> (HHTP) <sub>2</sub> , Ni <sub>3</sub> (HITP) <sub>2</sub>	Solvothermal	Chemiresistor	NO, H <sub>2</sub> S	0.1-80, 1- 80	_	160, 230	67
$Cu_3(HHTP)_2$ , $Ni_3(HHTP)_2$	Solvothermal	Chemiresistor array	$NH_3$ , $H_2S$ , $NO$	2.5-80	5-10	_	68
$Cu_3(HHTP)_2$ , $Cu_3(HITP)_2$ , $Ni_3(HITP)_2$	Drop-cast	Chemiresistor array	VOCs	200-2500	<del>_</del> ,	_	69
$Cu_3(HITP)_2$	Drop-cast	Chemiresistor	$NH_3$	0.5-10	_	< 1000	70

thus it is a difficult target for chemiresistor sensor detection. To address this challenge, chemiresistor devices prepared from Cu<sub>3</sub>(hexaiminobenzene)<sub>2</sub> (Cu<sub>3</sub>HIB<sub>2</sub>) thin films were shown to sense practically relevant concentrations of CO2 (400-2500 ppm) with a sensitivity nearly independent of the relative humidity level.<sup>52</sup> The high density of NH moieties on hexaiminobenzene promotes the formation of acid-base adducts or bicarbonate salts between CO2 and Cu3HIB2. The formation of these adsorbed CO2 species caused e withdrawal from the MOF, resulting in charge traps that affected charge mobility and consequently resistance.

Xu and co-workers were the first to demonstrate thin films (<100 nm) of conductive 2D MOFs integrated into chemiresistor devices (Fig. 3).66 They developed a spray LBL method whereby solutions of the metal precursor and organic ligand of Cu<sub>3</sub>(HTTP)<sub>2</sub>, as well as a rinsing solvent, were sequentially sprayed directly onto a chemiresistor device. They found that -OH functionalization on the substrate acted in the same way as a SAM for adhering and orienting MOF thin films. Each spray cycle of this method grew approximately 2 nm of Cu<sub>3</sub>(HTTP)<sub>2</sub> on the device surface. When exposed to NH<sub>3</sub> vapor, the Cu<sub>3</sub>(HTTP)<sub>2</sub> chemiresistor displayed an increase in resistance. Ultraviolet photoelectron spectroscopy found that the Fermi level of the Cu<sub>3</sub>(HTTP)<sub>2</sub> film increased by 1.13 eV after exposure to NH3, indicating that NH3 binding was n-type doping in Cu<sub>3</sub>(HTTP)<sub>2</sub>, a p-type semiconductor. This spraycoating technique was adapted to grow van der Waals stacked dual MOF thin films directly on chemiresistor devices (Fig. 4).65

In this work, a conductive 2D MOF thin film, Cu-HHTP, was first grown onto the chemiresistor device through spraycoating, followed by the growth of a molecular sieving MOF, Cu-TCPP (tetrakis(4-carboxyphenyl)porphyrin), thin film on top. The sensitivity of only the Cu-HHTP thin film toward NH<sub>3</sub> and benzene was tested, and it was found to have a much higher sensitivity to NH3 than benzene because of the electrondonating character of NH3. However, the growth of the molecular sieving Cu-TCPP above Cu-HHTP caused lower sensitivity toward NH3 than benzene, thus reversing the selectivity. This modulation in gas selectivity was caused by the chemisorption of NH<sub>3</sub> molecules within the Cu-TCPP layer, which prevents NH<sub>3</sub>, but not benzene, from reaching the underlying Cu-HHTP thin film.

Recent examples of conductive MOFs prepared from a mixture of two ligands have been shown to modulate the sensing properties of these materials as compared to their single-ligand counterparts. Kitagawa, Otake, and co-workers synthesized dual-ligand conductive MOF, Cu<sub>3</sub>(HHTP)(THQ) (THQ = tetrahydroxy-1,4-quinone), which showed intermediate conductivity and surface area ( $\sim 10^{-5} \text{ S cm}^{-1}$ ;  $\sim 440 \text{ m}^2 \text{ g}^{-1}$ ) between  $Cu_3HTTP_2$  ( $\sim 10^{-3}$  S cm<sup>-1</sup>;  $\sim 540$  m<sup>2</sup> g<sup>-1</sup>) and  $Cu_3THQ_2 (\sim 10^{-8} \text{ S cm}^{-1}; \sim 140 \text{ m}^2 \text{ g}^{-1}).^{62} \text{ A thick film of this}$ dual-ligand MOF was deposited on a chemiresistor device through drop-casting. Surprisingly, the lower conductivity baseline of Cu<sub>3</sub>(HHTP)(THQ) as compared to Cu<sub>3</sub>HHTP<sub>2</sub> made the dual-ligand MOF more sensitive to small charge transfers, resulting in good discrimination of NH3 at low concentrations

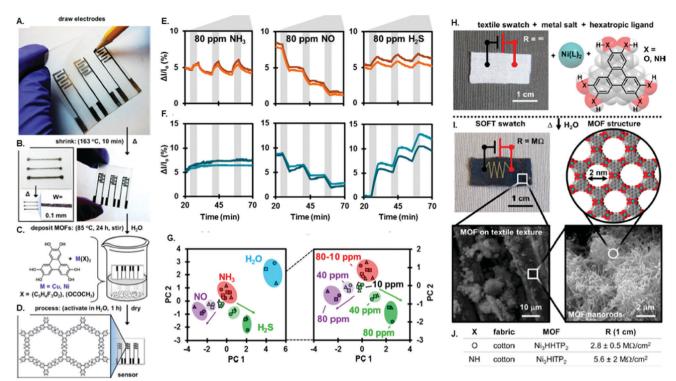


Fig. 2 Solution-based growth of 2D conductive MOFs on various substrates. (A) Photograph showing the process of drawing electrodes on a shrinkable polymeric film with a commercial HB (hard black) pencil. (B) Shrinking of the film (10 min, 163 °C) miniaturizes lateral features of the electrodes (W = wire width). (C) Solution-based growth of MOFs onto the device. (D) Schematic illustration of the resulting MOF-based chemiresistive sensors on the surface of a shrinkable polymeric film. Representative sensing traces for (E) Cu<sub>3</sub>HHTP<sub>2</sub> and (F) Ni<sub>3</sub>HTTP<sub>2</sub> exposed to 80 ppm of various gases three times. (G) PCA discrimination of different gases and concentrations. (H) Starting materials for SOFT-sensors: a cotton swatch (no conductivity), the organic triphenylene-based ligand (HHTP or HATP), and metallic node (Ni-(OAc)<sub>2</sub> or NiCl<sub>2</sub>). A photograph of the cotton swatch is shown. (I) Solvothermal condensation of these reagents in water produces conductive smart fabric sensors: textiles coated with nanoporous MOF. Macroscopic through molecular level detail is shown, from a photograph of cotton SOFT sensor postreaction (top left), to scanning electron micrographs detailing MOF coating on fibers (bottom left), and characteristic MOF nanorod texture (bottom right), to space-filling model of MOF (top right). (J) Sheet resistance measurements for smart fabric sensors prepared in this work. (A)-(G) was adapted with permission from J. Am. Chem. Soc., 2016, 28(15), 5264-5268. Copyright 2016 American Chemical Society. (H)-(J) was with permission from J. Am. Chem. Soc. 2017, 139(46), 16759-16767. Copyright 2017 American Chemical Society

(1-100 ppm) and a LOD down to 0.02-0.35 ppm. In another work, Xu and co-workers adapted their spray LBL method to assemble a dual-ligand conductive MOF thin film directly onto a chemiresistive device. 61 A mixed ligand solution was used during the spray LBL assembly to produce thin films of  $Cu_3(HHTP)_{2-r}(HITP)_r$ . They observed that HITP doping below 1.0 mol% resulted in a conductivity increase of the MOF thin film; however, doping above 1.0% resulted in decreased conductivity due to diminished crystallinity. Besides conductivity, the selectivity of  $Cu_3(HHTP)_{2-x}(HITP)_x$  toward different gas analytes was modulated by tuning the doping concentration. Selectivity for benzene vs. NH<sub>3</sub> was improved 220% for 10 mol% HITP doping as compared to undoped Cu<sub>3</sub>(HHTP).

#### 2.2 Chemicapacitive sensors

Unlike chemiresistors, which require sensing materials with high conductivities, chemicapacitors can utilize non-conducting materials as the dielectric sensing material. Many examples of non-conductive MOFs integrated as dielectric films in chemicapacitors have been shown well before the first MOF chemiresistor was demonstrated.<sup>48</sup> The working principle behind

chemicapacitor sensors is the relationship between analyte adsorption in the dielectric material and the subsequent modulation of the material's permittivity constant caused by changes in charge distribution. Both parallel plate design,<sup>58</sup> as well as complementary metal oxide semiconductor-compatible IDE design<sup>53-57,59,60</sup> have been used to make MOF film-based chemicapacitors. While parallel plate capacitor devices may have higher nominal capacitance and sensitivity, IDE chemicapacitors have the same benefits of IDE chemiresistors, including ease of process, miniaturization, low power consumption, and inexpensive manufacturing cost.71 A challenge of capacitor sensing devices is the requirement for AC, which adds AC frequency as another parameter for optimization. Overall, chemicapacitors are promising devices for the incorporation of MOF thin films because of their simplified IDE design and the requirement for non-conductive sensing materials, of which the majority of MOFs are non-conductive.

Achmann and co-workers first demonstrated the integration of non-conductive MOF films on IDE devices by screen-printing MOF pastes on an IDE and heating to evaporate the solvent.<sup>72</sup> These devices were coupled to an impedance analyzer to

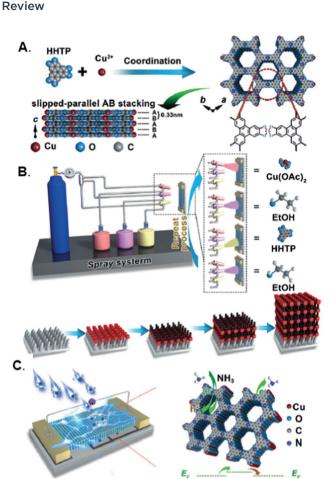


Fig. 3 Spray-coating of a 2D conductive MOF thin film on a chemiresistor device. Illustration of (A) the crystal structure of Cu<sub>3</sub>(HHTP)<sub>2</sub> and (B) the preparation of Cu<sub>3</sub>(HHTP)<sub>2</sub> thin-film gas sensors through successive spray-coating of metal linker solution, organic linker solution, and wash solvent. (C) Schematic of the chemiresistor gas sensor and possible gassensing mechanism for NH<sub>3</sub>. This figure was adapted with permission from Angew. Chem., Int. Ed., 2017, 56(52), 16510-16514. Copyright 2017, John C. Wiley and Sons, Inc.

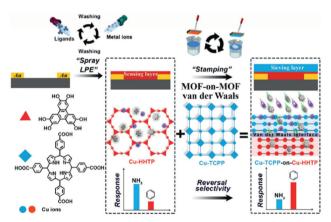


Fig. 4 Illustration of the preparation of MOF-on-MOF thin films by van der Waals integration and application of the films as highly selective benzene-sensing materials. This figure was adapted from Angew. Chem., Int. Ed., 2019, 58(42), 14915-14919. Copyright 2019, John C. Wiley and

monitor impedance between 1 Hz and 1 MHz in the presence of humidity and VOCs. The first MOF thin film chemicapacitor was demonstrated by Omran and co-workers, wherein crystalline and highly oriented Cu(bdc) thin films were grown on IDE devices functionalized with OH-terminated SAMs through an LBL procedure<sup>59</sup> for humidity and VOC sensing. Humidity is a common sensing target for chemicapacitors because of its large molecular dipole (1.85 D) and the high permittivity constant of liquid water (78.3). The choice of MOF used in a sensor must take chemical stability into account for corrosive targets such as H2S and NH3. Salama, Eddouadi, and co-workers developed rare earth (RE) MOFs with face-centered cubic (fcu) topology that are stable even in the presence of corrosive gases. These RE-fcu-MOFs were integrated into IDE capacitor devices via surface functionalization and solvothermal reaction in order to sense H<sub>2</sub>S or NH<sub>3</sub>, depending on the organic linker. <sup>56,60</sup> RE-fcu-MOF showed stability toward H<sub>2</sub>S for weeks, in contrast to other more common MOFs like Cu(bdc)-xH<sub>2</sub>O or ZIF-8, which decomposed due to metal sulfide formation in a short period of time.

Zhao and co-workers demonstrated how the selectivity of MOF chemicapacitors can be modulated with post-synthetic modifications to the MOF sensing layer.<sup>53</sup> Mg-MOF-74 films were grown on IDE devices via a solvothermal process and showed sensitivity toward both benzene vapor and CO<sub>2</sub>. However, after functionalizing the Mg-MOF-74 thin film with ethylenediamine, the chemicapacitor showed an approximately 60% decrease in benzene sensitivity and an approximately 25% increase in CO2 sensitivity. This effect was attributed to ethylenediamine binding to the OMS of Mg-MOF-74, which weakens  $\pi$ -complexation of the benzene molecules to the OMS, and the increased adsorption of CO<sub>2</sub> due to amine-CO<sub>2</sub> interactions.

Solvothermal syntheses of MOF thin films on surface functionalized devices is the most prevalent synthetic approach for chemicapacitors because of its wide applicability, potential for patterning, and ease-of-use. However, other methods such as electrochemical deposition and the use of metal oxide precursors have also shown success in chemicapacitor preparation.<sup>29,54</sup> Yuan et al. compared two synthetic methods for growing Ni-NDC (NDC = 2,6-naphthalenedicarboxylic acid) MOF thin films grown on an IDE device: (1) in situ solvothermal synthesis and (2) Ni(OH)<sub>2</sub> precursor conversion (Fig. 5).<sup>54</sup> The Ni-NDC MOF thin film grown through the solvothermal method showed poorly adhered, corrugated thin films on the surface of the IDE device. In contrast, MOF growth via a Ni(OH)<sub>2</sub> precursor showed compact, homogeneous thin films that displayed no delamination from the substrate. This Ni-NDC thin film IDE device was used to sense benzene down to 25 ppm.

#### 2.3 Field effect transistor sensors

Field-effect transistor (FET) sensors are composed of conducting channels (typically the sensing material) that are modulated by electric fields generated by gate electrodes. The gate electrode may be separated from the conductive channel by a solid dielectric layer or a liquid electrolyte solution, depending on the application. The type of gate electrode set-up used in an FET depends on the application. For example, an FET sensor of

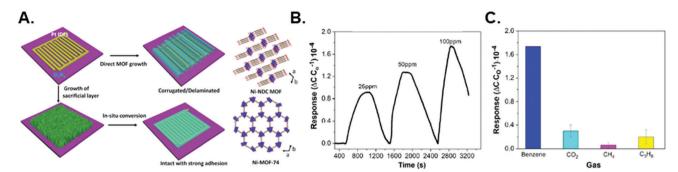


Fig. 5 On-chip template-directed conversion of metal hydroxides to MOF thin films as chemicapacitor-based gas sensors. (A) Scheme of direct solvothermal growth on IDE device *versus* template-directed growth on an IDE device *via* a sacrificial metal hydroxide layer. (B) Dynamic response of the Ni-NDC MOF-coated capacitive sensor upon exposure to various concentrations of benzene vapor at room temperature. (C) Selectivity of the Ni-NDC MOF-coated sensor toward different analytes. The concentration of benzene is 100 ppm, whereas the concentration of the other gases is 1000 ppm. This figure was adapted with permission from *ACS Appl. Mater. Interfaces*, 2020, **12**(32), 36715–36722. Copyright 2020, American Chemical Society.

gases used the solid back-gate architecture, while an FET sensor of aqueous biomolecules would use a liquid gate architecture. There have been few examples of MOF thin films integrated into FET devices. 73,74 Duan and co-workers have demonstrated for the first time the application of conductive 2D MOFs, in this case Ni-HTTP, as the conducting channel of an FET sensor.<sup>75</sup> In this work, Ni-HTTP thin films were prepared on the surface of an FET device through an interface-assisted/solvothermal synthesis. Briefly, ozone-treated FET devices are contacted with the liquidair interface of the Ni-HTTP precursor solution and then heated in a water bath at 65 °C for a set time period. The optimal Ni-HTTP FET device showed excellent FET properties with a charge mobility of 45.4 cm<sup>2</sup> V<sup>-1</sup> s<sup>-1</sup> and an on/off current ratio of  $2.29 \times 10^3$ . A liquid gate composed of phosphate buffer solution and a silver reference electrode was placed above the Ni-HTTP FET device in order to sense different concentrations of gluconic acid in solution. As the gluconic acid concentration increased, the FET's conductance decreased and threshold voltage shifted towards more negative gate voltages, thus demonstrating the potential for a MOF-based FET sensor device.

#### 2.4 Device integration considerations for electrical sensors

Defects in MOF film quality such as cracks, inhomogeneity, and poor substrate adhesion can lead to device-to-device variation in electrical properties (*e.g.* resistance, capacitance), limited device lifetime, and leakage current in the case of alternating current (AC) chemicapacitors. <sup>54,58</sup> Moreover, as device miniaturization continues apace, fine area control becomes important for the integration of MOF thin films into devices, especially when incorporating electrically conductive MOF thin films. <sup>8</sup> Thus, more sensitive and controllable synthetic methods such as SAM-directed LbL <sup>76</sup> and metal oxide templating are crucial for the realization of MOF-based electrical sensors.

# 3. Optical MOF thin film sensors

Optical sensors utilizing MOF thin films offer many advantages, from low equipment costs, rapid response times, and recyclability.

Consequentially, it is anticipated that this sensor class will continue to receive significant attention, particularly for the detection of various gases. MOF-based optical sensors rely on changes to the MOF's photofunctional properties (e.g. reflectance,<sup>77</sup> refractive index (RI),<sup>78</sup> absorbance,<sup>79</sup> photoluminescence, 13,80-83 etc.) in response to interaction with variables of interest, such as ions, gases, and temperature.84,85 Photofunctionality can be introduced into MOF thin films through a variety of ways:86 the use of chromophoric organic linkers within the MOF structures, 87 optically-active metal centers (particularly emissive lanthanides), 88 or via host-guest interactions, in which photoactive ions, 89,90 metal complexes, 91,92 molecules, 93-96 nanoparticles, 97-100 and/or other species are encapsulated by the MOF. MOF-based optical sensors are intriguing because they typically exhibit rapid response times (often on the order of seconds), 101-104 high sensitivity (ppb or lower LOD),  $^{103,105,106}$  recyclability (*via* removal of analyte from the MOF after each sensing cycle), 103,104,107-109 and usually can be integrated with inexpensive, portable equipment,90 such as fiber optic-based platforms. 104,110,111 Indeed, many optical sensors allow for naked-eye detection of analytes and require only simple laser pointers, light-emitting diodes, UV lamps, or other portable excitation sources for operation. 103,112,113 Thus, provided MOF films can be tailored to be sufficiently selective for analytes of interest for "real-world" deployment, 114 optical sensors represent a powerful platform for detecting a wide range of analytes. In this section, we describe optical sensing mechanisms, materials, strategies, and techniques using MOF thin films. Table 3 is included here to summarize important parameters from a range of thin-film based-optical sensing studies, with additional details and examples provided in subsequent sections.

### 3.1 Luminescence-based sensors

**3.1.1 Luminescent sensor readouts.** MOF materials may emit energy in the form of light upon excitation from a range of sources: incident light (photoluminescence), heat (thermoluminescence), electric current (electroluminescence), chemical reactions (chemiluminescence), mechanical stress

The Fire   Fleetrodeposition   Emission quenching   Cri	Material	Film growth method	Sensing mechanism	Target analyte	Reversible?	Film thickness (μm)	Ref
Electrodeposition	[{[Eu(HBPTC)(H <sub>2</sub> O) <sub>2</sub> ]·2DMF} <sub>2</sub> ]	Electrodeposition	Emission quenching	CO <sub>3</sub> <sup>2-</sup>	_	1	115
Tib(p(Dn)(  +pon)(				$Cr^{3+}$ ,	Yes	30-70	126
The	Th(enon)(Henon)(H (O) }	Dron-east	Emission quenching	Cr O 2-	Vac		127
Electrodeposition   Emission quenching   Endersystem   Electrodeposition   Emission quenching   Endersystem   Emission quenching   Endersystem   Emission quenching   Eph-   Ves   —				C1 <sub>2</sub> O <sub>7</sub>			128
Drop_cast   Emission quenching   Emission quenc				Cu <sup>2+</sup>			129
				Fe <sup>3+</sup>			103
Drop-cast   Emission warelength shift   Hg²   Yes   —				Hg <sup>2+</sup>			112
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$			Posterior de la contra	2+	***		420
$ [Tb([I,IO_1]_n], [Tb([I,IO_1]_n]], [Tb([I,IO_1]_n], [Tb([I,IO_1]_n], [Tb([I,IO_1]_n], [Tb([I,IO_1]_n]], [Tb([I,IO_1]_n], [Tb([I,IO_1]_n], [Tb([I,IO_1]_n]], [Tb([I,IO_1]_n], [Tb([I,IO_1]_n]], [Tb([I,IO_1]_n]$	$Zn_2(NDC)_2(DPTTZ)$	Drop-cast		Hg	Yes	_	130
Togolar	$[Tb(L)(H_2O)_5]_n$		Emission quenching		_	_	131
County	$[\text{TbL}(\text{NO}_3)_3]_n \cdot 2\text{C}_4\text{H}_8\text{O}_2$	Drop-cast		Zn <sup>2+</sup>	Yes	_	132
The companies				Acetaldehyde	Yes	_	133
	$[(CuCN)_3L\cdot(guest)_x]_n$	•		Acetonitrile	Yes	_	134
[Th(TATMA)(H <sub>2</sub> O) 2H <sub>2</sub> O} <sub>1</sub>   Drop-cast   Emission quenching   CO <sub>2</sub>   Yes   0.20	Ln(TTA/TAA)@HiO-67			NH <sub>2</sub>	_	50	135
				14113		30	155
ZIF-8	$\{[Tb(TATMA)(H2O)\cdot 2H2O\}_n$			Antibiotics		_	113
ZIF-8				$CO_2$	Yes	0.20	104
TD-BTC RL-MOF RL		1					110
Ru-MOF Eu-NDC@HPAN LbL Emission quenching Fatty acid binding Protein  Eu-NDC@HPAN LbL Emission ratiometric Emission quenching Eu-NDC@HPAN Lincolor Spin-coat Emission ratiometric Emission quenching Electrodeposition Emission quenching Electrodeposition Emission quenching Solvothermal  RPM-3  Reflector Emission quenching Solvothermal Emission quenching Solvothermal Shift  RUB-Ca(TBTC) <sub>2</sub> (DMF) <sub>2</sub> ]-4DMF  REmplated Absorption wavelength Solvothermal Shift  RUB-Ca(TBTC) <sub>2</sub> (DMF) <sub>2</sub> ]-4DMF  REmplated Emission quenching Solvothermal Shift  RUB-Ca(TBTC) <sub>2</sub> (DMF) <sub>2</sub> ]-4DMF  REmplated Emission quenching Solvothermal Shift  RUB-Ca(TBTC) <sub>2</sub> (DMF) <sub>2</sub> ]-4DMF  REmplated Emission quenching Solvothermal Shift  RUB-Ca(TBTC) <sub>2</sub> (DMF) <sub>2</sub> ]-4DMF  REmplated Emission quenching Solvothermal Shift  RUB-Ca(TBTC) <sub>2</sub> (DMF) <sub>2</sub> ]-4DMF  REmplated Emission quenching Solvothermal Shift  RUB-Ca(TBTC) <sub>2</sub> (DMF) <sub>2</sub> ]-4DMF  REmplated Emission quenching Solvothermal Shift  RUB-Ca(TBTC) <sub>2</sub> (DMF) <sub>2</sub> ]-4DMF  REmplated Emission quenching Solvothermal Shift  RUB-Ca(TBTC) <sub>2</sub> (DMF) <sub>2</sub> ]-4DMF  RUB-Ca(TBTC) <sub>2</sub> (DMF) <sub></sub>				_		_	125
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	Ru-MOF			Fatty acid binding	Yes	3–17	136
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	Eu-NDC@HPAN	LbL	Emission ratiometric	Formaldehyde	_	2-4	124
$ \begin{tabular}{l l l l l l l l l l l l l l l l l l l $	UiO-66-(COOH) <sub>2</sub> -Ag-Eu	Spin-coat	Emission ratiometric	Formaldehyde	_	_	137
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	CuBTC	Drop-cast		Humidity	Yes	540	138
$ [NH_2(CH_3)_2]_2[Cd_{17}(L)_{12}(\mu_{37} \\ H_2O)_2]_2 solvent \\ ZD_1(BMF)_2(H_2O)_2]_2 solvent \\ ZD_1(BCPA) & Drop-cast \\ ZD_1(BTC)_2 & Electrodeposition \\ ZD_1(BTC)_2 & Electrodeposition \\ ZD_1(BTC)_2 & Electrodeposition \\ ZD_1(BTC)_2 & Dip-cat \\ ZD_2(BCA)_3(H_2O)(DMF)_3]_2 0.5DMF \cdot H_2O)_3, \\ ZD_2(DMF)_2 0.5DMF \cdot$	ZIF-8/PDMS	Dip-coating	RI change	Methane	Yes	120	111
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	$\{[Eu_2(TDC)_3(CH_3OH)_2]\cdot CH_3OH\}$	Electrodeposition	Emission quenching	Nitroaromatics	Yes	7	139
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$		Drop-cast	Emission quenching	Nitroaromatics	Yes	_	140
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	Zn-BCPA	Drop-cast	Emission quenching	Nitroaromatics	_	1	122
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	$(Zn_3(BTC)_2)$	Electrodeposition	Emission quenching	Nitroaromatics	Yes	1-18	141
RPM-3 Templated Emission Olefins Yes 3.5 solvothermal enhancement [Co <sub>3</sub> (TBTC) <sub>2</sub> (DMF) <sub>2</sub> ]-4DMF Templated solvothermal enhancement [Co <sub>3</sub> (TBTC) <sub>2</sub> (DMF) <sub>2</sub> ]-4DMF Templated solvothermal shift Solvothermal Spectroscopy Solvothermal Solvotherm			RI change		_	~100	142
$[Co_3(TBTC)_2(DMF)_2] \cdot 4DMF \qquad   Solvothermal   S$	$\{[Eu_2(BCA)_3(H_2O)(DMF)_3]\cdot 0.5DMF\cdot H_2O\}_n$		Emission quenching	Nitrofuran	Yes	6	107
$ [Co_3(TBTC)_2(DMF)_2] \cdot 4DMF \qquad Templated solvothermal shift \\ CuBTC \qquad Dip-coat \qquad Absorption wavelength shift \\ NH_2-MIL-88B \qquad Spin-coat \qquad Reflection spectroscopy \\ Tb(BTC)(H_2O) \qquad Dip-coat \qquad Emission quenching organic vapors Yes o.48 \\ TBF-8 \qquad Dip-coat \qquad RI change organic vapors Yes o.48 \\ TBF-8 \qquad Dip-coat \qquad RI change organic vapors Yes o.44 \\ TBF-8(Nile red) \qquad Dip-coat \qquad RI change organic vapors Yes o.41 \\ TBF-8(Nile red) \qquad Dip-coat \qquad RI change organic vapors Yes o.41 \\ TBF-8(Nile red) \qquad Dip-coat \qquad RI change organic vapors Yes o.41 \\ TBF-8(Nile red) \qquad Dip-coat \qquad RI change organic vapors Yes o.41 \\ TBF-8(Nile red) \qquad Dip-coat \qquad Emission quenching organic vapors Yes o.21 \\ TBF-8(Nile red) \qquad Dip-coat \qquad Emission quenching organic vapors Yes o.21 \\ TBF-8(Nile red) \qquad Dip-coat \qquad Emission quenching organic vapors Yes o.42 \\ TBF-8(Nile red) \qquad Dip-coat \qquad Emission quenching organic vapors Yes o.42 \\ TBF-8(Nile red) \qquad Dip-coat \qquad Emission quenching organic vapors Yes o.42 \\ TBF-8(Nile red) \qquad Dip-coat \qquad Emission quenching organic vapors Yes o.44 \\ TBF-8(Nile red) \qquad Dip-coat \qquad Emission quenching organic vapors Yes o.45 \\ TBF-8(Nile red) \qquad Dip-coat \qquad Emission quenching organic vapors Yes o.45 \\ TBF-8(Nile red) \qquad Dip-coat \qquad Emission quenching organic vapors Yes o.45 \\ TBF-8(Nile red) \qquad Dip-coat \qquad Emission quenching organic vapors Yes o.45 \\ TBF-8(Nile red) \qquad Dip-coat \qquad Emission quenching organic vapors Yes o.45 \\ TBF-8(Nile red) \qquad Dip-coat \qquad Emission quenching organic vapors Yes o.45 \\ TBF-8(Nile red) \qquad Dip-coat \qquad Emission quenching organic vapors Yes o.45 \\ TBF-8(Nile red) \qquad Dip-coat \qquad Emission quenching organic vapors Yes o.45 \\ TBF-8(Nile red) \qquad Dip-coat \qquad Emission quenching organic vapors Yes o.45 \\ TBF-8(Nile red) \qquad Dip-coat \qquad Emission quenching organic vapors Yes o.45 \\ TBF-8(Nile red) \qquad Dip-coat \qquad Emission quenching organic vapors Yes o.45 \\ TBF-8(Nile red) \qquad Dip-coat \qquad Emission quenching organic vapors Yes o.45 \\ TBF-8(Nile red) \qquad Dip-coat \qquad Emission quenching organic vapors Yes o.46 \\ TBF-8(Nile red) \qquad Dip-coat \qquad Di$	RPM-3			Olefins	Yes	3.5	121
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	$[Co_3(TBTC)_2(DMF)_2] \cdot 4DMF$	Templated	Absorption wavelength	Organic vapors	Yes	0.58	109
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	CuBTC		Absorption wavelength	Organic vapors	Yes	0.05-0.1	143
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	NH <sub>2</sub> -MIL-88B	Spin-coat	Reflection	Organic vapors	Yes	0.3-1	108
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	Tb(BTC)(H <sub>2</sub> O)	Dip-coat		Organic vapors	_	7	144
$ \begin{array}{cccccccccccccccccccccccccccccccccccc$			Reflectance				77
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	ZIF-8	Dip-coat		Organic vapors	Yes	1	78
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$							145
$\begin{array}{cccccccccccccccccccccccccccccccccccc$		1	Emission				96
$\begin{array}{cccccccccccccccccccccccccccccccccccc$	MIL-100(In):Tb	Solvothermal		$O_2$	Yes	2.5	146
$ \begin{array}{cccccccccccccccccccccccccccccccccccc$	. ,						147
$\begin{array}{cccccccccccccccccccccccccccccccccccc$		•					102
$ \begin{array}{cccccccccccccccccccccccccccccccccccc$			Emission wavelength		Yes	4-5	123
$ \begin{array}{cccccccccccccccccccccccccccccccccccc$	$[Eu_4(NDC)_6(H_2O)_5]\cdot 3H_2O$	Electro-deposition		Picric acid	Yes	0.05	105
$Gd_{0.9}Tb_{0.1}HL$ Templated Emission ratiometric Temperature Yes 10		•		trans,trans-Muconic			148
	$\rm Gd_{0.9}Tb_{0.1}HL$		Emission ratiometric		Yes	10	149
	UiO-66-Eu		Emission ratiometric	Temperature	_	30-270	150

(mechanoluminescence), 119 and ionizing radiation (radioluminescence)120 are all examples of stimuli capable of producing a luminescent response. The luminescent signal may change in a

variety of ways in the presence of target analytes: the emission intensity may be enhanced, <sup>96,121</sup> reduced (quenched), <sup>122</sup> or the emission energy may shift. <sup>123</sup> In some cases, two separate

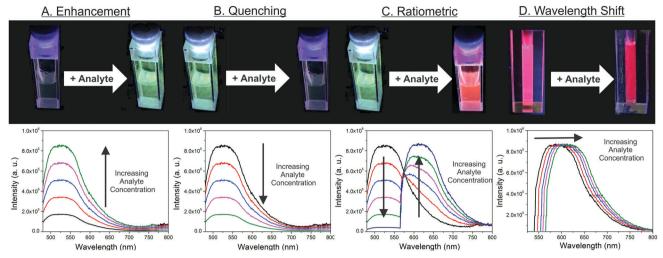


Fig. 6 Summary of steady-state luminescence-based sensing mechanisms. (A) Analyte enhances the sensor emission intensity. (B) Analyte reduces, or quenches, the sensor emission intensity. (C) Analyte enhances the intensity of one emission peak and reduces the intensity of a second peak, producing a change in the intensity ratios between the two peaks. (D) The analyte changes the emission energy of the sensor.

emission peaks may respond to an analyte, and the ratio of the peak areas or intensities may be used for chemical sensing. 124 Examples of these steady-state sensing mechanisms are summarized in Fig. 6. Additionally, it is also possible to use time-resolved luminescence techniques, in which the emission lifetime changes as a function of analyte concentration. 125

3.1.2 Design of luminescent MOFs. There are a multitude of strategies that may be employed to impart luminescence to the MOF (Fig. 7). MOFs are often comprised of rigid, aromatic organic linkers that are inherently luminescent. 151 Highly emissive linkers may be designed by functionalizing chromophores such as pyrene, 152 naphthalene, 124,130 and anthracene, 122 among others with groups capable of binding to metal centers (e.g. carboxylates, amines, etc.).86 Conversely, MOFs may employ emissive metal centers, often using lanthanide elements, 115,128 to produce a luminescent response. Terbium and/or europium are

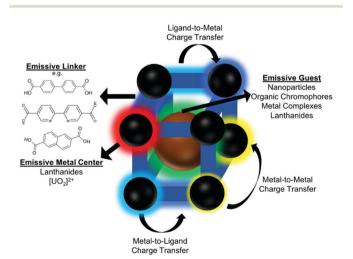


Fig. 7 Summary of methods and processes for the design of luminescent MOFs.

most often used due to their intrinsically high quantum yield in the visible emission range (relative to the other lanthanides), 153,154 while near-infrared (NIR)-emitting MOFs usually incorporate ytterbium, neodymium, and/or erbium. 155 NIR-emitting MOFs are less commonly used in part due to higher equipment costs for NIR detection; however, emission in this range is optimal for optical fiber and biological applications. 155 Importantly, while lanthanides produce intense, narrow emission bands that are desirable for sensing applications, the absorption transitions that give rise to this emission are parity forbidden; therefore, sensitizer molecules (such as the linkers used in MOFs) are typically required to first transfer energy to the lanthanide metal centers. 90 In rare cases, MOFs may also be designed with emissive uranyl [UO<sub>2</sub>]<sup>2+</sup> centers. <sup>156,157</sup> It is important to note that the emission observed from MOFs often is not solely from the ligand or the metal, but may often be influenced by charge transfer processes between the ligands and/or metal centers. 158

In addition to linkers and metal-centers, luminophores may be taken into the MOF pores (e.g. host-guest interactions) to promote luminescence. The luminophore may be added during synthesis for encapsulation 136,159,160 or using post-synthetic techniques. Post-synthetic uptake of luminophores may be driven by van der Waals forces, 161 electrostatic interactions (i.e. anionic MOFs encapsulating cations), 162,163 and/or coordination with unbound functional groups on the linker, 164 to name a few examples. Common luminescent guests include lanthanides, 101,162 emissive nanoparticles, 159 metal complexes, 136 and organic molecules.147

3.1.3 Device integration considerations for luminescent sensing. In general, luminescence-based sensing does not require the MOF to be in thin film form. Indeed, MOFs are most commonly dispersed in solution or used as a dry powder for luminescent sensing. 83,84,165,166 However, MOFs in thin film form can offer benefits including enhanced emission intensity (due to a reduction in self-quenching) and faster analyte uptake. 129

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Furthermore, the use of MOFs in thin film form can offer advantages in terms of portability and recyclability. In many designs, MOF "test strip" films have been developed with sufficiently strong emission that inexpensive, handheld light sources such as laser pointers may be used as the excitation source with detection made by the naked eye. 112 Several examples of portable luminescent sensing films are displayed in Fig. 8. These films are typically fabricated by deposition on substrates such as glass, 128,129,144 metal oxides, 102 and paper, 148,167 or by dispersing the MOF in glues<sup>113</sup> and transparent polymers<sup>131</sup> such as poly(methyl methacrylate). 127 Additionally, it is often

straightforward to reuse immobilized MOF thin films across multiple sensing cycles, whereas MOFs dispersed in solution are typically more difficult to recover and regenerate (Table 4). For example, MOF thin film ion sensors are often regenerated by exposing the film to a chelating agent (e.g. ethylenediaminetetraacetic acid) or fresh solvent. 130 Portability and recyclability are crucial, practical considerations for minimizing costs and potential commercialization. 90

3.1.4 Examples of luminescence-based MOF thin film sensors. As shown in Table 3, luminescence-based MOF thin film sensors have been designed to detect a range of analytes,

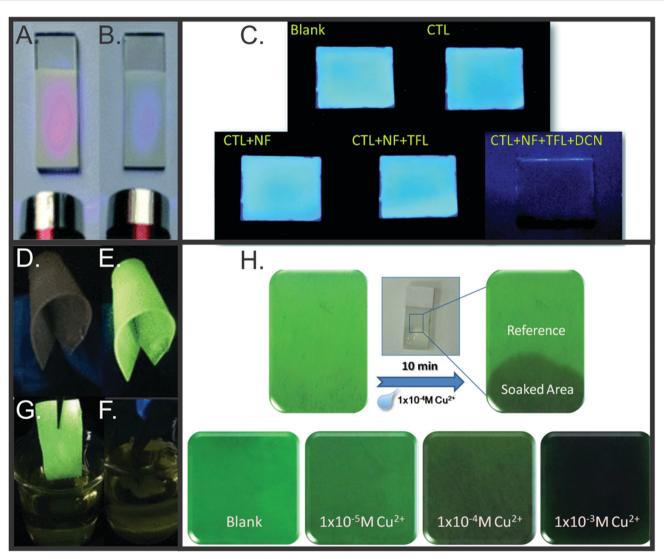


Fig. 8 Examples of portable luminescent sensing MOF films. A mercury(II) sensor based on a {[Eu<sub>2</sub>(bqdc)<sub>3</sub>(H<sub>2</sub>O)(DMF)<sub>3</sub>]-0.5DMF·H<sub>2</sub>O}<sub>n</sub> (BQDC = 2,2biguinoline-4,4-dicarboxylate). Under illumination from a handheld UV light, the MOF film exhibits red Eu-centered emission (A), which is selectivity quenched by mercury ions (B). Reproduced with permission from J. Mater. Chem. A, 2013, 1, 11312-11319. Copyright 2013, Royal Society of Chemistry. (C) A blue-emitting thin film (H<sub>3</sub>O)[Zn<sub>2</sub>L(H<sub>2</sub>O)]-3NMP-6H<sub>2</sub>O under UV light is exposed to various pesticides (100 µL of 0.01 M solutions): chlorothalonil (CTL), nitrofen (NF), trifluralin (TF), and 2,6-dichloro-4-nitroaniline (DCN). Noticeable quenching is observed in the presence of DCN. Reproduced with permission from RSC Adv., 2019, 9, 38469–38476. Copyright 2019, Royal Society of Chemistry. A flexible film of {[Tb(TATMA)(H<sub>2</sub>O)·2H<sub>2</sub>O}<sub>n</sub> dispersed in a gelatinous glue under ambient (D) and UV (E) light. Emission is quenched upon exposure to 0.5 mM of the antibiotic nitrofurantoin (F), with emission restored upon film removal (G). Reproduced with permission from Inorg. Chem., 2019, 58, 7746-7753. Copyright 2019, American Chemical Society. (H) A film of a terbium-succinate MOF under UV light. The MOF emission is gradually quenched with increasing Cu<sup>2+</sup> exposure. Reproduced with permission from Sens. Actuators, B, 2015, 220, 779-787. Copyright 2015, Elsevier, Inc.

Table 4 Strategies for regenerating MOF thin films for optical sensing

Sensing target	Recycling technique
Ions/ molecules	Exposure to fresh solvent, 103,127,130 chelating agent (e.g. ethylenediaminetetraacetic acid)129
Solvents	Desolvation (heat/vacuum), <sup>134,140</sup> drying, <sup>133</sup> rinsing with fresh solvent <sup>105,107,139</sup>
Gases/vapors Temperature	Gas purge, <sup>104,111,146</sup> vacuum <sup>147</sup> Temperature change <sup>149</sup>

included gases, 146 organic vapors, 96 ions, 112 explosives, 122 pharmaceuticals, 123 and even temperature. 149

Ion sensors. The rapid, sensitive, and selective detection of ions has utility in a wide range of areas, including prospecting for high-value elements,90 identifying heavy metal contaminants in water sources, <sup>127,131</sup> and medical diagnostics, <sup>103,132</sup> for example. MOFs may interact with ions through binding sites within the MOF pores, 103,131 or through electrostatic interactions<sup>101</sup> (e.g. the use of a cationic MOF to sense anions and anionic MOFs to sense cations). Selective ion detection is often enabled via the inhibition (for "turn off" sensors) or promotion (for "turn on" sensors) of energy transfer states within the MOF upon ion binding.82 For example, Yang and co-workers demonstrated that Cu2+ selectively undergoes partial

ion exchange with terbium in a terbium-succinate MOF, which disrupts the sensitization of terbium and reduces emission (Fig. 8H). 129 For "turn off" sensors, insights into the emission quenching mechanism may be gained through a Stern-Volmer analysis of the quenching 106,168 and through time-resolved studies.169

A key challenge is the development of sensors that exhibit a selective emission response only in the presence of a target ion. hence it is crucial for the sensor to be tested on a multitude of potential interferants that may be encountered in "realworld" systems, such as environmental waters and biological matrices. 114 Therefore, cross-sensitivity studies analyzing the impact of competing ions are crucial to evaluating the sensor efficacy. Examples of such studies for ion sensors are shown in Fig. 9.

Molecule sensors. In addition to detecting ions in solution, MOF thin films may also be used for the luminescence-based detection of a wide range of molecules, such as solvents, 124,133 biomolecules, 136,148 and pharmaceuticals. 113,123 As such, the thin films have potential utility in medical diagnostics, 136 pollution monitoring, 105,124,133 and explosives detection, 139 among others. The sensing considerations for molecules are similar to those described above for ion detection, in that experimentation in environmentally relevant condition and

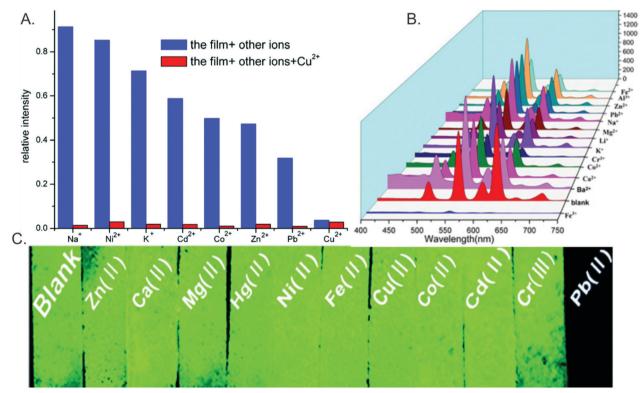


Fig. 9 Examples of interferant studies conducted with luminescent MOF thin film ion sensors. (A) Relative emission intensity from [Tb<sub>2</sub>(BDC)<sub>3</sub>(H<sub>2</sub>O)<sub>4</sub>]<sub>n</sub> in the presence of 1 mM cation solutions with (red) and without (blue) Cu(ii) added. Reproduced with permission from RSC Adv., 2014, 4, 58178-58183. Copyright 2014, Royal Society of Chemistry. (B) Emission spectra of Eu<sub>0.24</sub>Tb<sub>0.76</sub>-BHM-COOH in the presence of 0.01 M of various cations. Reproduced with permission from Spectrochim. Acta, Part A, 2020, 230, 118084. Copyright 2020, Elsevier, Inc. (C) Image of [Tb(L)(H<sub>2</sub>O)<sub>5</sub>]<sub>n</sub> under UV light in the presence of 1 mM cation solutions. In each example, quenching is most pronounced selectively for the ion of interest. Reproduced with permission from J. Mater. Chem. A, 2017, 5, 10200-10205. Copyright 2017, Royal Society of Chemistry.

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selectivity studies are both critical. A diversity of sensing mechanisms can be observed for molecular targets. For example, an Eu MOF linked by 2,6-naphthalenedicarboxylate (NDC) grown as a thin film on hydrolyzed polyacetonitrile was selectively degraded by formaldehyde (as evidenced by XRD), leading to a ratiometric response in which emission signal from freed NDC was enhanced while Eu emission was quenched. 124 Conversely, a lanthanum MOF with encapsulated Tb ions (Tb@La-MOF) exhibits selective quenching from acetaldehyde exposure without undergoing any structural change. Rather, quenching is observed because an acetaldehyde absorption band overlaps with the Tb@La-MOF excitation band, 133 and this competitive absorption mechanism has been exploited for other MOF thin-film sensors as well (Fig. 10). 105,139,148

In addition to quantitatively detecting individual compounds, MOF thin film sensors have also been designed to distinguish analytes of interest by monitoring responses to multiple

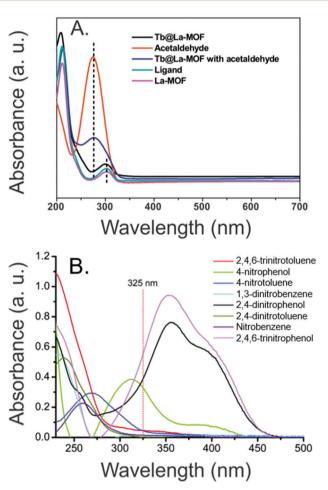


Fig. 10 Examples of competitive absorption guenching mechanisms for "turn-off" sensors of molecules. (A) Absorption bands of acetaldehyde overlaps strongly with the excitation band of Tb@La-MOF, causing a selective reduction in emission. Reproduced with permission from Sens. Actuators, B., 2019, 300, 126985. Copyright 2019, Elsevier, Inc. (B) An Eu-TDC MOF selectively detects nitrophenols over other nitroaromatic compounds due to competitive absorption at 325 nm. Reproduced with permission from Analyst, 2016, 141, 4502-4510. Copyright 2016, Royal Society of Chemistry

emission peaks. For example, a MOF thin film containing both Tb and Eu was developed for distinguishing different pharmaceutical molecules by comparing changes in the intensity ratios of the Tb and Eu peaks following exposure to each molecule (Fig. 11A). 123 Similarly, alterations in observed emission color can be used as a visual indicator of the concentration of a single analyte. For example, a thin film of Tb encapsulated by a zinc, 2-sulfonvlterephthalate, and 4.4-bipvridine based MOF (MOF-SO<sub>3</sub><sup>-</sup>) on test paper exhibits distinct color changes in the presence of the benzene biomarker trans, trans-muconic acid. This effect is due to quenching of both the Tb and MOF emission peaks, thus providing a pathway towards rapid diagnostics (Fig. 11B).148

Gas/vapor sensors. MOF thin films may also be employed as luminescent sensors in the gas phase. Often, guest ions/molecules within the MOF pore are used to ensure a selective response upon interaction with target gasses, producing a range of innovative sensing mechanisms. Sensitive sensors for oxygen have been developed based upon the quenching of emission from terbium<sup>146</sup> and pyrene<sup>147</sup> within MOF hosts. An Eu-functionalized UiO-67 MOF exhibited selective emission enhancement in the presence of ammonia vapors. This enhancement was attributed to hydrogen bonding between the NH<sub>3</sub> gas and the MOF linker, which increased the linker triplet state energy and facilitated energy transfer to the Eu (Fig. 12A). 135 Similarly, a dual-emissive UiO MOF (zirconium linked with 1,2,4,5-benzenetetracarboxylate) was functionalized with Ag and Eu ions for formaldehyde sensing. When Eu alone

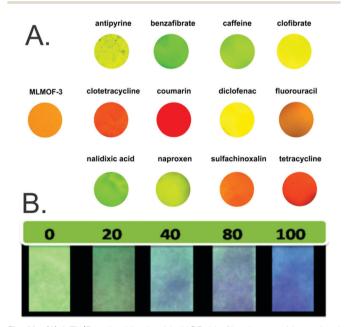


Fig. 11 (A) A Tb/Eu mixed lanthanide MOF thin film that provides a visual method for distinguishing various antibiotic molecules. Reproduced with permission from Sens. Actuators, B, 2018, 257, 931-935. Copyright 2018, Elsevier, Inc. (B) A test paper with a thin film of Tb@MOF-SO3<sup>-</sup> that provides a visual method for rapidly quantifying between 0-100 ppm of trans, trans-muconic acid. Reproduced with permission from Inorg. Chem., 2018, 57, 7815-7824. Copyright 2018, American Chemical Society.

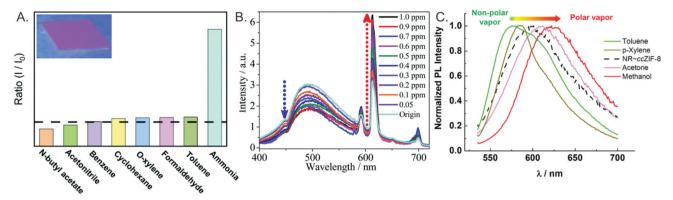


Fig. 12 Examples of luminescent MOF thin film vapor sensors. (A) Interaction between ammonia and the linker of an Eu-functionalized UiO-67 MOF leads to enhanced Eu emission (inset: Eu@UiO-67 under 310 nm light). Reproduced with permission from Dalton Trans., 2020, 49, 15663-15671. Copyright 2020, Royal Society of Chemistry. (B) Incorporation of Eu and Ag ions into the pores of a UiO MOF produces a ratiometric response upon formaldehyde interaction with Ag. Reproduced with permission from Nanoscale, 2016, 8, 12047-12053. Copyright 2016, Royal Society of Chemistry. (C) A thin film of Nile Red dye@ZIF-8 exhibits vapor-chromic luminescence upon vapor absorption. Reproduced with permission from Adv. Opt. Mater., 2020, 8, 2000961. Copyright 2020, John C. Wiley & Sons, Inc.

is in the MOF, only Eu emission is observed. The presence of Ag<sup>+</sup> decreases the energy transfer between the MOF and the Eu, enabling emission peaks from both Eu and the MOF to be observed. Upon formaldehyde interaction with Ag, a ratiometric response occurs in which the Eu peak is enhanced and the MOF peak is quenched (Fig. 12B). 137 Nile red dye embedded in a ZIF-8 thin film exhibits a vapor-chromic luminescence response in which non-polar vapors induce a blueshift in the emission wavelength and more polar vapors induce a red-shift. Importantly, the use of a MOF matrix (relative to Nile Red embedded on a thin film of polystyrene beads) enhanced the sensor sensitivity due to greater interfacial area for vapor interactions (Fig. 12C).<sup>96</sup>

#### 3.2 Absorbance-based sensors

3.2.1 Absorbance sensor readout. A range of MOF thin films have been developed that exhibit selective changes to its absorbance spectrum upon analyte interaction. Readouts may include changes in the absorption, 138 transmission, 104 or reflectance spectrum. 108 The readout mechanisms shown in Fig. 6 are also applicable here: peaks may gain or lose intensity as a function of analyte interaction, or may shift in energy. The underlying mechanism for these changes in the optical spectrum are often driven by RI changes 77,78,104,108,111,145 and/or changes in the coordination environment of MOF metal centers. 109,138 As with luminescent-based sensors, absorbance sensors exhibit desirable characteristics such as the ability to use relatively low-cost, portable equipment, <sup>104</sup> recyclability, <sup>78,104,110</sup> and rapid response times. 111,143 Examples of sensor readouts are shown in Fig. 13.

3.2.2 Design of absorbance-based MOF thin film sensors. The design rules for absorbance-based MOF thin films are generally simpler than those in the development of luminescent MOFs. The encapsulation of optically-active guest molecules is less common for absorbance sensors. Instead, absorption peaks arising from aromatic ligands or d-band transitions in transition metal centers typically provide the needed optical response. 104,109,138 For sensors relying upon RI changes, designing MOFs with the

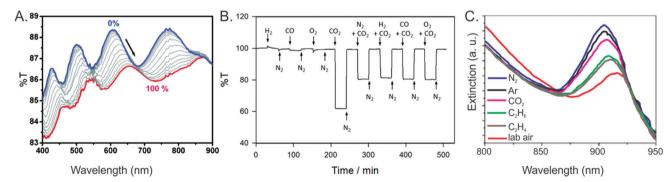


Fig. 13 Examples of typical readouts used in absorbance-based MOF thin film sensors. (A) A Fabry-Pérot device uses ZIF-8 thin films to detect propane vapor (0% to 100%), detected by tracking shifts in the reflectance interference peaks due to RI changes. Reproduced with permission from J. Am. Chem. Soc., 2010, 132, 7832-7833. Copyright 2010, American Chemical Society. (B) ZIF-8 film on an optical fiber detects CO2 gas by monitoring changes in the transmission spectra, which are altered due to a change in RI. Reproduced with permission from ACS Sens., 2018, 3, 386-394. Copyright 2018, American Chemical Society. (C) A thin film of CuBTC on silica beads exhibits gas-dependent shifts in its near-infrared extinction, which is dependent upon the amount of gas absorbed as well as the RI. Reproduced with permission from Adv. Mater., 2011, 23, 4449-4452. Copyright 2011, John C. Wiley & Sons, Inc.

ability to "breath" (e.g. expand or contract upon gas sorption) enhances sensitivity (vide infra). 108,109

3.2.3 Device integration considerations for absorbance sensors. Unlike luminescence-based MOF sensors that can often be used in either powder or film form, it is often essential for absorbance-based MOF sensors to be in thin film form. Continued synthetic innovations to improve MOF thin film quality will therefore enable more absorbance-based sensors to be developed, with a corresponding increase in performance. For example, reflection interference peaks (Fabry-Pérot fringes) are often used as a sensor readout, and the number and energies of these peaks are directly influenced by MOF thin film thickness (Fig. 14).<sup>77</sup> Further, sensor performance is often highly sensitive to film thickness and film quality, as defects lead to increased scattering and poorer performance. 104 Film thicknesses for this sensor class are typically on the hundreds of nanometer scale, on par with the wavelength of visible light. 108 MOF thin films for absorbance-based sensing have been grown on a range of substrates, including optical fibers, 104,111 silicon, 77,78,108 gratings,145 glass,145 alumina,109 and others.

3.2.4 Examples of absorbance-based sensors. Absorbancebased MOF thin film sensors are generally used to quantitatively detect gases of interest, or to differentiate between gases, a process governed by the RI of each gas as well as the selectivity and capacity of the MOF for each gas. 77,108 For example, Kim et al. developed a selective, sensitive sensor for CO<sub>2</sub> (Fig. 13B) over other gases with similar refractive indices (e.g. N<sub>2</sub>, H<sub>2</sub>, CO and O<sub>2</sub>) using a 200 nm ZIF-8 thin film grown directly on an optical fiber core (Fig. 15A-C). Because ZIF-8 exhibits an adsorption capacity for CO2 that is over 10 times higher than N2 and similar gases, CO2 adsorption by ZIF-8 leads to a RI change in the sensing layer, monitored by a decrease in transmission. 104 Doping ZIF-8 with cobalt provided additional optical features (from d-d transitions) in the visible spectra, and the optical fiber platform was found to be significantly more sensitive than measurements conducted on a planar substrate. 170 Similarly, a fiber optic platform with ZIF-8 dispersed in polydimethylsiloxane polymer was capable of detecting 1% methane in N2, 111 while ZIF-8 growth on an optical fiber long period grating has been used to differentiate organic vapors such as ethanol and methanol. 145 CuBTC, which has an optical transition near ~700 nm from d-d transitions, has also been integrated onto an optical fiber platform for humidity detection (Fig. 15D). Coordination of water with Cu leads to a blue-shift in this transmission peak, enabling sensitive water detection of 40 ppb by volume. Similarly, a nitrobenzene sensor was developed based upon RI changes by gluing a single crystal of CuBTC onto an optical fiber tip. 142

Other sensing platforms involve growth of the MOF thin film onto planar substrates, with measurements made either visually or using a spectrometer (e.g. Fig. 14). Rather than being used to detect a single analyte, the sensors typically exhibit different responses to different gases. For example, a composite film of CuBTC and silica beads displays gas-dependent extinction shifts in the NIR, where different pure gases produce different wavelengths of maximum intensity (Fig. 13C). 143 Similarly, a film of NH<sub>2</sub>-MIL-88B (Fe(III) and 2-aminoterephthalic acid) undergoes gas-dependent changes in its reflectance spectrum, enabling visual differentiation of several different pure gases. 108 A film of UiO-66 demonstrated a similar response to various organic vapors, including ethanol; a selfassembly growth mechanism producing a mesoporous UiO-66 film significantly outperformed a sensor using a dense UiO-66 layer grown solvothermally, highlighting the important role of the MOF growth technique in sensor development.<sup>77</sup>

## 4. Acoustic MOF thin film sensors

Acoustic-based sensors such as QCM and SAW devices have been functionalized with MOF films to great effect. The working principle behind acoustic-based sensors is the relationship between the mass of a piezoelectric crystal and its resonant frequency induced by an alternating electric field. In the case of QCM, small gravimetric changes caused by adsorption on a quartz piezoelectric crystal surface modulate the resonant shear wave frequency across the crystal. This relationship between change in mass  $(\Delta m)$  and frequency  $(\Delta f)$  is described by the Sauerbrey equation (eqn (1)):

$$\Delta f = \frac{2f_o^2}{A\sqrt{p_q\mu_q}}\Delta m \tag{1}$$

in which  $f_0$  is the resonant frequency of the quartz piezoelectric crystal, A is the piezoelectrically active crystal area,  $p_q$  is the

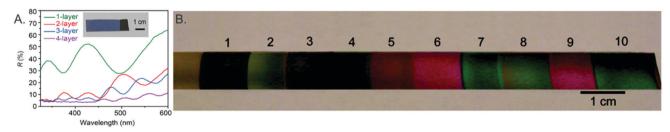
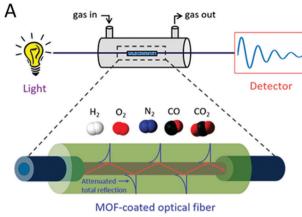


Fig. 14 (A) Evolution of the reflectance spectra of UiO-66 monolayers grown on a silicon substrate (inset: photograph of a single monolayer). Both the number and energies of interference peaks change as a function of the MOF layer thickness. Reproduced with permission from ACS Appl. Mater. Interfaces, 2019, 11, 21010–21017. Copyright 2019, American Chemical Society. (B) Photograph of 1 to 10 layers (~100 to 1000 nm) of ZIF-8 on a silicon substrate. Color changes due to alterations in reflectance are observable to the naked eye. Reproduced with permission from J. Am. Chem. Soc., 2010, 132, 7832–7833. Copyright 2010, American Chemical Society.



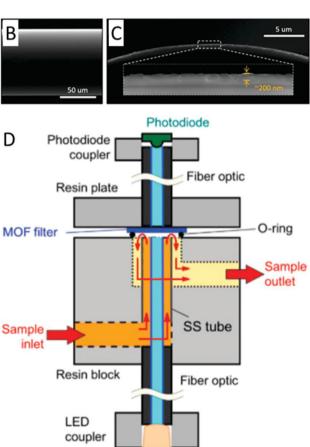


Fig. 15 Examples of fiber optic MOF thin film sensor platforms. (A) A thin coating of ZIF-8 onto an etched optical fiber is used to detect CO<sub>2</sub> selectively over competing gases. (B) Side view and (C) cross-section of the optical fiber functionalized by 200 nm ZIF-8. Reproduced with permission from ACS Sens., 2018, 3, 386-394. Copyright 2018, American Chemical Society. (D) Schematic of a fiber optic humidity sensor using CuBTC as the sensing layer. Reproduced with permission from Anal. Chim. Acta, 2015, 886, 188-193. Copyright 2015, Elsevier, Inc

density of quartz, and  $\mu_q$  is the shear modulus of quartz. In the case of SAW devices, gravimetric changes modulate the surface acoustic wave frequency propagated along the surface of a

piezoelectric substrate. Functionalization of these devices with nanoporous materials, including MOF films, has been shown to significantly increase sensitivity and selectivity toward various gases and vapors. One advantage of the excellent correlation between frequency and mass in acoustic-based devices is that it allows gas adsorption isotherm experiments to be performed with thousandfold (µg vs. mg) less MOF material. A conventional 9 MHz OCM sensor can ideally sense mass changes down to the nanogram level, thus modification with a MOF film that concentrates gas molecules on the device surface is a promising avenue for gas detection. MOF thin film acousticbased sensors are summarized in Table 5.

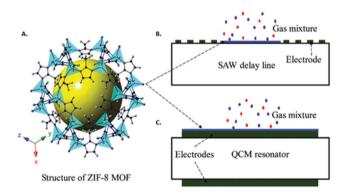
#### 4.1 QCM sensors

Dual layer MOF films wherein a "shell" MOF layer chosen for its molecular sieving effect is grown above a "core" MOF layer chosen for its high gas uptake has been successfully demonstrated on OCM-based sensors. A "Janus" film composed of two different MOFs was shown to significantly improve selectivity toward methanol without diminishing sensitivity. 171 In this work three films were prepared via LbL growth on a pyridylterminated SAM QCM:  $[Cu_2(ndc)_2(dabco)]_n$  above  $[Cu_2(HOOC)]_n$  $(CH_2)_2OCNH-bdc)(NH_2-bdc)(dabco)]_n$  (A@C),  $[Cu_2(HOOC(CH_2)_2-$ OCNH-bdc)(NH<sub>2</sub>-bdc)(dabco)]<sub>n</sub> grown above  $[Cu_2(ndc)_2$ - $(dabco)_n$  (C@A), and a randomly mixed film of  $[Cu_2(ndc)_2]$ (dabco)<sub>n</sub> and  $[Cu_2(HOOC(CH_2)_2OCNH-bdc)(NH_2-bdc)(dabco)]$ <sub>n</sub> (AC). Of the three films, only C@A showed excellent selectivity for methanol and nearly complete exclusion of n-hexane from the QCM surface. This selectivity for methanol over hexane is attributed the small polar pores of [Cu<sub>2</sub>(HOOC(CH<sub>2</sub>)<sub>2</sub>OCNHbdc)(NH<sub>2</sub>-bdc)(dabco)]<sub>n</sub>, which prevent the large non-polar hexane molecules from reaching the underlying [Cu<sub>2</sub>(ndc)<sub>2</sub>  $(dabco)_{n}$  layer. The underlying  $[Cu_{2}(ndc)_{2}(dabco)]_{n}$  layer has the highest adsorption capacity of the two MOFs, thus sensitivity toward methanol was not diminished. Similar to this work, hierarchical structured core-shell MOF architectures on QCM devices were prepared to achieve highly selective VOC sensors based on size selectivity.<sup>172</sup> In this work, small pore "shell" MOF films on large pore "core" MOF films, both based on  $[Zn_4O(3,5-dialkylcarboxypyrazolate)_3]_n$  structures, were grown via liquid phase epitaxy (LPE) on QCM devices (Fig. 17). These hierarchical core/shell films were able to selectively adsorb VOC molecules purely based on size while still maintaining high adsorption capacity because of the underlying large pore MOF film. This size exclusion effect was demonstrated with two polar VOCs: methanol and isopropanol. The isotherm of a hierarchical film composed of a small pore shell-layer of [Zn<sub>4</sub>O(3,5dialkylcarboxypyrazolate) $_{3}$  $_{n}$  and a large pore core-layer of  $[Zn_4O(3,5-dimethyl-4-carboxypyrazolate)_3]_n$  showed a nearly constant adsorbed amount when the methanol partial pressure was constant and the isopropanol partial pressure was increased. This experiment shows the effectiveness of dual layer MOF films for achieving both molecular sieving and high gas adsorption capacity.

The array approach has been applied to QCM devices in order to discriminate between various gases. The straightforward

Table 5 MOF thin film acoustic-based sensors

Material	Film growth method	Device type	Target analyte	Sensing range (ppm or %)	Film thick- ness (μm)	LOD (ppb)	Ref
CuBTC, MIL-53, CuBPDC	Spray LbL	QCM	VOCs	1.0-40		_	175
Chiral and achiral MOF array	LbL	QCM	Chiral/achiral VOCs	10-100	_	_	176
CuBTC	LbL and LPE	Microcantilever	H <sub>2</sub> O, MeOH, EtOH, CO <sub>2</sub>	N/A	0.1	_	187
$[Cu_2(ndc)_2(dabco)]n$ $[Cu_2(NH_2-bdc)_2(dabco)]_n$	LbL	QCM	MeOH, hexane	5-100%	0.05	_	171
CuBTC, MOF-5	LbL	QCM	VOCs	100-1000	0.5	1000 (toluene)	189
$[Zn_4O(3,5-dialkylcarboxypyrazolate)_3]_n$ -based core-shell	LbL	QCM	VOCs	1-100%	_	_	172
MIL-53	Solvothermal	QCM	Hexane	3-40%	3	_	190
MIL-101	Langmuir– Blodgett	QCM	$CO_2$	20-100%	0.05	_	20
MIL-96(Al)	Langmuir–Blod- gett/Schaefer	QCM	$CO_2$	20-100%	0.2	_	186
[Al(OH)(1,4-NDC)]	Drop-cast	QCM	Pyridine vapor	0.3-25	_	40	183
KAUST-7, KAUST-8	Spin-coat	QCM	$SO_2$	5-150	2	5000	184
MIL-101	Drop-cast	QCM	VOCs	5-700	3	1603 (pyridine)	185
MOF-14	Drop-cast	QCM	Benzene	0.5-10	_	150	191
[Cu <sub>3</sub> (4-(2-carboxyphenoxy)-isophthalic acid)]		QCM	Humidity	20-96.7% RH	_	_	192
CAU-1	N/A	QCM	Methanol	32-128	_	_	193
MIL-101	Drop-cast	QCM	Formaldehyde	2-700	3	1790	194
PIZA-1	Spray LbL	QCM	Benzene	N/A	0.340 - 0.732	_	195
ZIF-8	LPE	QCM/SAW	$CO_2$ , $CH_4$	1–100%, 20– 100%	0.3	_	180
$Cu_2(ndc)_2(dabco)$	Metal oxide template	QCM	$CO_2$	5-100%	0.6	_	196
MFU-4, MFU-4l	Solvothermal	SAW	$CO_2$	1 ppm-100%	0.2	1000	179
ZIF-8/ZIF-67	Spin-coat	SAW	Acetone, etha- nol, NH <sub>3</sub>	5-25	_	1100, 500, 1600	181
CuBTC	LbL	SAW	Humidity	3-14 800	0.2	280	197
UiO-66-NH <sub>2</sub>	Spray-coat	Magnetoelastic resonator	Toluene	3728-8869	15	_	246



**Fig. 16** Schematic of (A) a ZIF-8 crystal and its films applied to (B) SAW and (C) QCM transducers. This figure was adapted with permission from *Nanoscale*, 2018, **10**, 8075–8087. Copyright 2018, Royal Society of Chemistry.

transduction pathway for QCM, whereby the gas uptake for the partial pressure of a particular gas is directly related to the change in acoustic frequency *via* the Sauerbrey equation, has allowed for various mathematical investigations into theoretical MOF QCM arrays. <sup>173,174</sup> In one of these mathematical studies, *a priori* data of the gas adsorption properties for individual MOFs, as determined

by molecular modelling and simulation, are used to curate the ideal MOF selection for sensor arrays. 173 One experimental example of a QCM array composed of three different surfacemounted MOF (SURMOF) thin films (CuBTC, Cu-benzene dicarboxylate, and Cu-biphenyl dicarboxylate) was applied toward the discrimination of different volatile plant oil odors. 175 This 3 SURMOF QCM array, in combination with k-nearest neighbour analysis algorithms, was able to discriminate between six VPOs and their binary mixtures with nearly 100% accuracy. Another work constructed a QCM array of 3 chiral MOF and 3 achiral MOFs in order to discriminate between enantiomers of various odor molecules (Fig. 18). 176 Interestingly, the chiral MOFs could discriminate between isomer pairs, whereas the achiral MOF devices showed identical responses to isomer pairs. Combination of the chiral and achiral MOF devices into a six-device array led discrimination of five enantiomeric molecule pairs with 96% average accuracy.

#### 4.2 SAW sensors

MOF thin films have been grown on SAW-based sensors as a sensitizing material for various gas sensing applications. In the case of QCM devices, a shear acoustic wave is propagated through the piezoelectric quartz crystal such that only

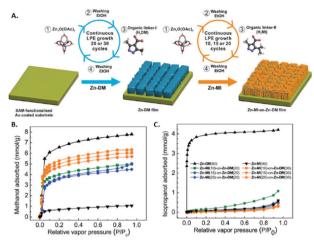


Fig. 17 Hierarchical structuring of MOF thin films on QCM substrates for selective adsorption. (A) Schematic illustration of the continuous stepwise LPE fabrication of heterostructured [Zn<sub>4</sub>O(carboxypyrazolate)<sub>3</sub>]<sub>n</sub> thin films, wherein the core-layer MOF is composed of Zn-DM and the shell-layer MOF is composed of Zn-MI. Single-component (b) methanol and (c) isopropanol adsorption isotherms at 25 °C for Zn-MI, Zn-DM and various Zn-MI(x)-on-Zn-DM(y) heterostructured films using an environmentalcontrolled QCM. Note that x and y represent the number of deposition cycles for Zn-MI and Zn-DM, respectively. This figure was adapted with permission from J. Mater. Chem. A, 2015, 3, 23385-23394. Copyright 2015, Royal Society of Chemistry.

gravimetric changes on the sensing material affect changes in acoustic frequency. In contrast, the acoustic wave in SAW devices runs along the surface of the device and is thus affected by different properties of the sensing material besides gravimetric changes, such as roughness and conductivity. While this adds a complicating factor to SAW in comparison to QCM, SAW devices have the advantage of operating at frequencies 2 to 3 orders of magnitude greater than QCM devices. This higher operating frequency of SAW devices results in increased sensitivity towards gravimetric changes. For example, a ZIF-8 thin film-coated SAW device that operated at a resonant frequency of 860 MHz displayed four times greater sensitivity toward CO2 than a similar ZIF-8 thin film-coated SAW device that operated at a resonant frequency of 430 MHz. 177

For the reasons mentioned above, thin and uniform sensitizing films are required for SAW-based gas sensors. Therefore, any incorporation of a MOF sensitizing layer must utilize synthetic methods that produce well-controlled thin films on areas typically smaller than 1 cm<sup>2</sup>. For example, a LbL method was shown to grow dense "nbo" topology MOF thin films (100-200 nm) on the surface of SAW devices with good mechanical coupling.<sup>178</sup> These MOF thin film SAW devices were applied toward organic vapor sensing. In another work, a solvothermal method, in conjunction with a small PDMS reaction chamber deposited on the SAW device, was used to grow a thin film of 200 nm MFU-4 NPs. 179 The high sensitivity and fast response time of SAW devices made it feasible to perform gas uptake kinetic experiments at different temperatures and to determine the activation energies for a series of different gas uptakes. Liquidphase epitaxy has been used to directly grow a ZIF-8 thin film on

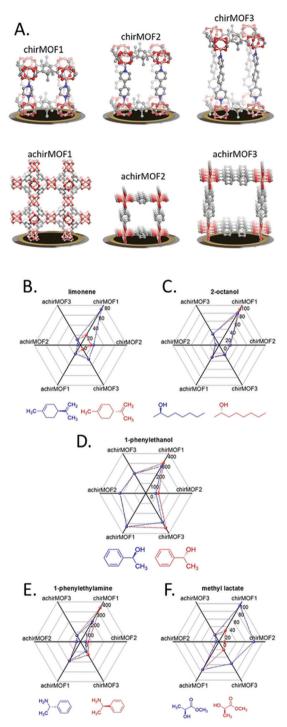


Fig. 18 Enantioselective e-nose array prepared with chiral and achiral MOFs. (A) Chiral (top) and achiral (bottom) MOF structures coating the QCM sensors of the e-nose. The term chirMOF1 denotes Cu<sub>2</sub>(DCam)<sub>2</sub>-(dabco), chirMOF2 is Cu<sub>2</sub>(DCam)<sub>2</sub>(BiPy), chirMOF3 is Cu<sub>2</sub>(DCam)<sub>2</sub>-(BiPyB), achirMOF1 is CuBTC, achir-MOF2 is Cu(BDC), and achir-MOF3 is Cu(BPDC). Radar plots of the sensor response to the exposure of (B) (R)- and (S)-limonene, (C) (R)- and (S)-2octanol, (D) (R)- and (S)-1-phenylethanol, (E) (R)- and (S)-1-phenylethylamine, and (F) methyl (R)- and (S)-lactate. The R-enantiomers are plotted in red, S-enantiomers are plotted in blue. The concentration is 50 ppm. The axes of the radar plots are the negative values of the recorded frequency shifts in Hz at the end of each uptake period, averaged over 40 points. These values correspond to the averaged maximum signals. This figure was adapted with permission from Angew. Chem., Int. Ed., 2021, 60(7), 3566-3571. Copyright 2021, John C. Wiley and Sons, Inc.

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the surface of a Y–Z LiNbO $_3$  SAW device for the detection of CO $_2$  and CH $_4$ . Interestingly, the same difference in CO $_2$  and CH $_4$  adsorption isotherms for bulk ZIF-8 was reflected in the sensitivity difference of ZIF-8 thin film-coated SAW devices towards these gases. A type of SAW device called Love-wave devices are less affected by roughness or defectiveness of the sensing layer because a low propagation velocity guiding layer (e.g. SiO $_2$ ) is deposited above the piezoelectric material (e.g. quartz), thus limiting direct interaction between the acoustic wave and the sensing material. Therefore, the use of more rapid but less precise methods such as spin-coating can be used to deposit MOF films. In one example, an array of Love-wave devices spin-coated with ZIF type MOF NPs were used to discriminate between various breath biomarkers such as NH $_3$ , acetone, and ethanol.  $^{181}$ 

### 4.3 Device integration considerations for acoustic sensors

For QCM, the thickness of the MOF film is proportional to the sensitivity enhancement; however, past a certain thickness the correlation between mass change and frequency change (see Sauerbrey equation) no longer applies. MOF thin films are required for SAW devices since surface acoustic waves decay exponentially perpendicular to the surface.

MOF thin films have been grown or deposited on acoustic sensing devices using a variety of methods previously discussed. Similar to electrical sensing devices, methods such as drop-casting and spin-coating have been used to deposit thick films of MOF particles and nanoparticles on acoustic devices. 181-185 However, like electrical devices, thick film deposition methods can lead to nanoparticle agglomeration, which causes a loss in surface area and a consequent loss in sensitivity. The large planar dimensions of QCM devices make them well-suited for depositing thin films through the Langmuir-Blodgett (LB) or Langmuir-Schaefer (LS) method, wherein monolayers of MOF NPs at the solution-air interface are deposited on the quartz substrate. 20,186 The substrate orientation for LB is perpendicular to the solution surface, whereas the substrate orientation for LS is parallel to the solution surface. The gold electrodes on QCM devices provide a surface for SAM growth, which has been used to grow MOF thin films through LbL methods. 171,187-189 Unlike OCM devices, which can function with thick sensing films, the superficial nature of SAWs requires the

MOF sensing film on SAW devices to be thin (*i.e.* hundreds of nanometers). <sup>177,179,180</sup> Fig. 16 shows schematics of a ZIF-8 film on a QCM and SAW device.

## 5. Outlook and future directions

## 5.1 Composite MOF materials

An exciting aspect of MOFs is that they can easily be integrated with a variety of other materials. Indeed, as discussed in Section 3, optical sensors have been developed by exploiting host-guest interactions within the MOF, where lanthanide ions or dyes are used as the sensing material within a MOF scaffold. Beyond dyes or ions, sensors can be designed by combining MOFs with other materials that exhibit unique optical or physical<sup>200</sup> properties,<sup>201,202</sup> in which MOF pore functionalities tune selectivity while the second material provides a sensing response. Indeed, a range of MOF thin film composite materials have been developed for sensing applications, 203,204 where MOFs have been combined with functional materials such as graphene, 205,206 carbon dots, 100,207 perovskites, 208 polymers, 209,210 biomolecules, 210 quantum dots, 201 and various metal nanoparticles<sup>201,210,211</sup> (Fig. 19). In particular, metal NPs encapsulated within conductive MOFs create Schottky junctions at their interface, which act as active sites for analyte adsorption and charge transfer. 64 Similarly, metal nanoclusters composed of coinage metals (Cu, Ag, and Au) exhibit surface chemistry-dependent photoluminescence212,213 and can be linked together by rigid organic molecules to form MOFs with unique optical properties. 214,215 Emission from powders of these materials has been used for gas sensing applications, 216,217 indicating that these MOFs will likely have utility as thin film sensors. In addition to improving sensor performance, integrating MOFs with other materials may improve material stability, an important consideration for sensor deployment. 218,219 Another emerging technique is the preparation of thin films comprised of layers of different MOF structures (Fig. 20). The presence of multiple layers of different MOFs can enhance selectivity for analytes of interest by selectively absorbing analytes of interest and blocking potential interferants. 220-222

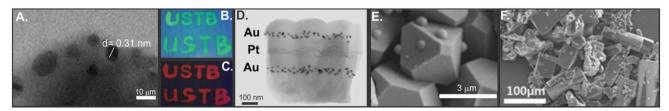


Fig. 19 Examples of MOF composite materials. (A) TEM image of an Eu-BTC MOF encapsulates a CH<sub>3</sub>NH<sub>3</sub>PBr<sub>3</sub> perovskite, producing a dual-emitting film that emits green light under 365 nm excitation (B) and red light under 254 nm excitation (C), reproduced with permission from *ACS Appl. Mater. Interfaces*, 2018, **10**, 27875–27884. Copyright 2018, American Chemical Society. (D) A ZIF-8 film produced with excellent spatial control of gold and platinum nanoparticles is shown in a TEM image, reproduced with permission from *Chem. Commun.*, 2014, **50**, 4296–4298. Copyright 2014, Royal Society of Chemistry. (E) An SEM image of polystyrene beads (620 nm) encapsulated by CuBTC MOF, reproduced with permission from *Nat. Commun.*, 2014, **5**, 1–9. Copyright 2014, Springer Nature. (F) SEM image of a zinc stilbene MOF encapsulating graphene oxide, reproduced with permission from *Nanoscale*, 2013, **5**, 8533–8540. Copyright 2013, Royal Society of Chemistry.

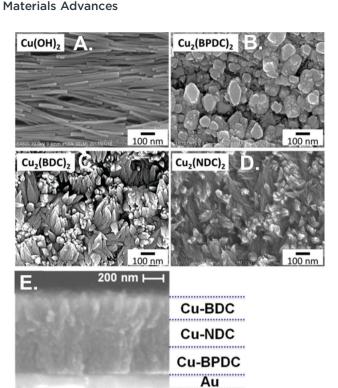


Fig. 20 Example of a 4 layer film of (A)  $Cu(OH)_2$ , (B)  $Cu_2(BPDC)_2$ , (C)  $Cu_2(BDC)_2$  and (D)  $Cu_2(NDC)_2$  MOFs, shown in a top-down view by SEM. Reproduced with permission from *Angew. Chem.*, 2019, **131**, 6960–6964. Copyright 2019, John C. Wiley and Sons, Inc. (E) SEM of a cross-section of three MOF layers grown on a gold substrate. Reproduced with permission from *Nano Lett.*, 2014, **14**, 1526–1529. Copyright 2014, American Chemical Society.

#### 5.2 Synthetic innovations

New synthetic innovations are needed to improve the scalability, quality, and generality (e.g. a method capable of accommodating a range of different MOF structures) of MOF thin film syntheses. One unique emerging method is to synthesize MOFs directly within the system of interest. For example, recently a terbium terephthalate MOF was synthesized within a living plant via immersion of the roots in MOF precursor, enabling luminescent detection of pollutants within the plant over time. 223 On-surface vapor-assisted crystallization (or conversion) synthesis<sup>224,225</sup> has been introduced as an efficient method in the synthesis of high quality MOF thin films. This method provides a more environmentally friendly process compared to conventional techniques by mitigating chemical waste and eliminating undesired side reactions. Other emerging synthetic processes gaining traction include supersaturation-driven crystallization and continuous flow-fluidic techniques (for liquid phase reactions) and gas phase processes (such as CVD, molecular vapor deposition, and atomic layer deposition), which offer excellent control over MOF film morphology and potential for scalability. 226,227 Such innovations are essential for translating MOF thin film technologies from the research lab into industrial-scale, commercial production.228

#### 5.3 Emerging sensing techniques

In addition to innovations in materials science, the development of new sensing techniques and platforms will further advance the field. Recently, several MOFs have been designed using qubit arrays and/or the encapsulation of quantum materials, 229-233 which may facilitate their use in quantum sensing techniques, an emerging field with the potential to offer unprecedented levels of sensitivity. 234,235 Nanocomposite films (Section 5.1) comprised of MOFs and plasmonic structures can be utilized for plasmonic sensing, another important sensing technique in which changes in the plasmon peak intensity or wavelength can track analytes of interest. 236 For example, changes in the plasmonic peak of silver nanoparticles (AgNPs) have been used to detect CO<sub>2</sub>; growing CuBTC over the AgNPs improved the signal 14-fold by concentrating the CO<sub>2</sub> near the AgNPs. 237 The near-infrared response of indium tin oxide (ITO) nanoparticles to CO2 has similarly been enhanced by CuBTC (Fig. 21A-D).<sup>238</sup> A fiber optic sensor comprised of a plasmonic gold film with a MOF coating was shown to sensitively detect alcohol vapors down to a 2.5 ppm level.<sup>239</sup> Additionally, plasmonic-MOF nanocomposites have promise in surface enhanced Raman spectroscopy-based sensor applications.240-245

A magnetoelastic sensor technique was recently demonstrated, in which UiO-66-NH<sub>2</sub> was spray-coated onto a rhombic-shaped strip of a ferromagnetic alloy, which could be used as a wireless sensor for toluene. Similar to SAW devices, a magnetoelastic sensor operates based upon the impact of mass change on the magnetoelastic resonance frequency.<sup>246</sup> The relatively simple fabrication process and high sensitivity indicate that MOF-based magnetoelastic sensors are worthy of additional study and optimization (Fig. 21E).

#### 5.4 Challenges

The ubiquity of water presents a challenge for most sensor applications, especially when utilizing a new material class like MOFs. The sensing of ions or other chemical species in water, as well as any sensing application done in humid environments, necessitates the use of materials that are (1) stable in aqueous solution or water vapor and (2) selective to the target analyte even in the presence of water. While water stability for the most studied MOF materials (e.g. CuBTC, ZIF-8) have been thoroughly investigated, the water stability of the majority of synthesized MOF materials have yet to be investigated. Though a thorough investigation must be done if a particular MOF thin film will be utilized as a sensing material, a few rules of thumb can be used to predict the relative stability and selectivity against water: (1) the absence of OMS, (2) hydrophobic organic ligands, and (3) strong metal-organic bonds (e.g. M(III)-carboxylate bonds). Post-functionalization of MOF thin films and compositing MOFs with hydrophobic polymer are two methods that have been applied to mitigate the negative effects of water.<sup>247–249</sup>

Beyond proof-of-principle and developmental testing in laboratory settings, consideration for the processability of

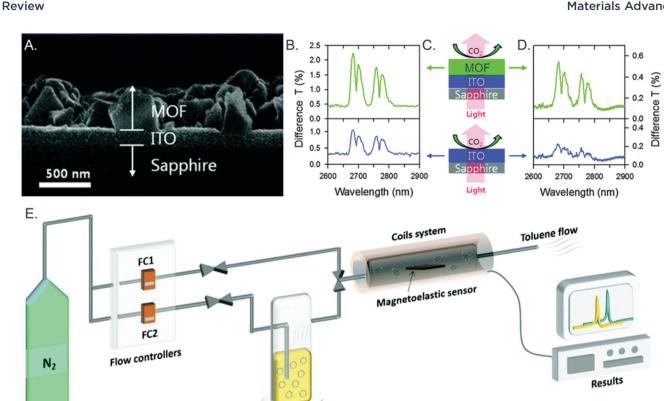


Fig. 21 Examples of emerging sensor techniques using MOF thin films. (A) SEM image of a plasmonic sensor consisting of a CuBTC thin film grown on a plasmonic indium tin oxide (ITO) substrate. The sensing response of the ITO plasmon peak from the MOF/ITO composite (top plots) is compared to that of bare ITO (bottom plots) under (B) high (100%) and (D) low (0.1%)  $CO_2$  conditions, with schematics of each set-up shown in (C). The presence of the MOF layer significantly enhances the sensor response to CO<sub>2</sub>. Reproduced with permission from J. Mater. Chem. C, 2015, 3, 2763–2767. Copyright 2015, Royal Society of Chemistry. (E) Schematic of a MOF-coated magnetoelastic sensing apparatus, which was used to detect toluene vapor. Reproduced with permission from J. Mater. Chem. C, 2020, 8, 13743-13753. Copyright 2020, Royal Society of Chemistry.

Toluene

MOF thin films within a sensor device architecture is required for any large-scale fabrication. Processability of a material includes factors such as device-to-device variability, patterning resolution, and processing time. Research into the integration of MOF thin films in electronic microdevices has found that a combination of bottom-up syntheses such as metal oxide templating with top-down methods such as photo- or e-beam lithography can be utilized to pattern MOF thin films within devices. 8,44,250-253 A recent example applied X-ray lithography and e-beam lithography to halogenated ZIF thin films (grown via chemical vapour deposition) to achieve film patterning with resolution reaching 10 µm and 50 nm, respectively. 254

## 6. Conclusions

Synthetic innovations enabling the development of MOF thin films have produced a range of exciting sensing technologies, capable of sensitive and selective detection of a range of analytes, including ions, small molecules, gases, temperature, and other analytes of interest using optical, electrical, and acoustic techniques. MOF thin film technologies have the potential to significantly benefit energy, manufacturing, environmental,

and medical sectors, among others. Fulfilling this potential requires (1) continued synthetic innovations to stabilize MOF thin films in harsh environments (e.g. high temperature, humidity, corrosive atmosphere, etc.), (2) developing strategies for mass production of thin films, and (3) continued innovations in the development of sensing techniques and platforms. Addressing such barriers to commercialization will be crucial for translating this transformative class of MOF sensing materials from the research lab into everyday products.

#### Notes

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## Author contributions

The manuscript was written through contributions of all authors. All authors have given approval to the final version of the manuscript.

## Conflicts of interest

There are no conflicts to declare.

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